

THE INSTITUTE OF ELECTRICAL AND ELECTRONICS ENGINEERS, In

445 Hoes Lane, P.O. Box 1331 Piscataway, NJ U.S.A. 08855-1331

ADVANCE PROGRAM



The First IEEE International Conference on Sensors

IEEE SENSORS 2002

June 11-14, 2002

Hyatt Orlando Orlando, Florida, U.S.A.

Sponsored by the IEEE Sensors Council

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PROGRAM HIGHLIGHTS

IEEE Sensors 2002

IEEE Sensors 2002 is the first conference organized by the IEEE Sensors Council. This Conference will bring together scientists, engineers, and business leaders who are interested in sensor science and technology. The fact that over 600 abstracts were received is strong evidence that the sensor community welcomes a general sensor conference backed by a professional society. The Technical Program Committee accepted 429 of the submissions.

The IEEE Sensors Council (www.ieee.org/sensors) has 26 member societies, with a combined membership of 260,000. With the great interest shown in IEEE Sensors 2002, the Council has decided to make IEEE SENSORS Conference an annual event.

A major advantage of having IEEE sponsorship is that the Conference Proceedings is an IEEE publication that is distributed to about 1000 libraries worldwide and is accessible on-line at IEEE Xplore (www.ieee.org/ieeexplore) for the foreseeable future.

A special attraction at IEEE SENSORS 2002 will be the banquet speaker, Dean Kamen, inventor of the Segway[™] Human Transporter, who will discuss the role of sensors in Segway and demonstrate the transporter.

We hope to see you at IEEE SENSORS 2002.

Keynote Speakers

This year's Keynote Speakers will be Dr. Amy E. Alving, Director, Special Projects Office, DARPA, who will speak on "Bio Warfare Defense Sensors: Applications and Research" and Professor Kazuhiro Hane, Tohoku University, who will speak on "New Optical Sensors Fabricated by Si."

Banquet Speaker

The banquet speaker will be Dean Kamen, inventor of the Segway™ Human Transporter. He will discuss the role of sensors in Segway and will demonstrate the transporter.

Tutorials

Eight tutorials in two parallel tracks (Sensors & Systems Applications and Engineering the Sensors of Tomorrow) will be offered on Tuesday, June 11, from 9:00 am to 5:30 pm. These tutorials will focus on the application and evaluation of sensors science and technology. Registration hours for the Tutorials are listed in the centerfold. See page 5 for further details.

Exhibition

The SENSORS 2002 Exhibition opens on Tuesday, June 11, at 7:00 pm with a reception and concludes on Friday, June 14, at 12:00 noon. Many of the leaders and innovators in the Sensors industry will be represented. See page 90 for a listing of exhibitors and show hours.

GENERAL INFORMATION

Logistics

IEEE SENSORS 2002 Conference will be held June 11–14, 2002, at the Hyatt Orlando Hotel in Kissimmee, Florida.

Sponsorship

The IEEE SENSORS 2002 Conference is sponsored by the IEEE Sensors Council.

Registration

Advance Registration is not required, but it is strongly encouraged for quick pick-up of registration materials, reduced fees, and for your convenience. The registration fee includes admission to all technical sessions, a single ticket to the Thursday evening banquet, all refreshment breaks, and a copy of the Proceedings. On-line registration is also available through the IEEE SENSORS 2002 Web site (http://www.ieee.org/sensors) or complete the enclosed registration form (see centerfold), include your payment, and mail or fax to the address below. Checks should be made payable to IEEE SENSORS 2002 in U.S. currency drawn on a U.S. bank. Only credit card payments may be faxed.

Palisades Convention Management Attn: Jimmy Le (IEEE Sensors 2002) 411 Lafayette Street, Suite 201 New York, NY 10003 fax 212/460-5460

The deadline for receipt of Advance Registration is May 13, 2002. Requests for refunds must be made in writing and received no later than May 13, 2002. Confirmations will be mailed. However, confirmation of registration can also be made by calling 1-800-350-0111 or 212/460-9700.

Registration will take place in the Paradise Foyer of the Hyatt Orlando Hotel during the hours listed below.

Tuesday, June 11	7:30 am - 9:00 pm
Wednesday, June 12	7:30 am - 5:00 pm
Thursday, June 13	7:30 am - 5:00 pm
Friday, June 14	7:30 am - 3:30 pm

Hotel Accommodations

The meeting will be held at the Hyatt Orlando Hotel, located at 6375 Irlo Bronson Memorial Highway, Kissimmee, FL 34747; telephone 407/396-1234. A block of sleeping rooms has been reserved for attendees of the IEEE SENSORS 2002 Conference at the Hyatt Orlando. The special meeting rates are listed below.

Single Occupancy \$86 Double Occupancy \$106

Hotel reservations can be made on-line at the IEEE SENSORS Web site (www.ieee.org/sensors) or by calling 407/396-1234 prior to May 20. Reservations received after this date will be processed at the conference rate on a space availability basis only. When making reservations, please be sure to mention that you are attending SENSORS 2002.

Speaker's Prep Room

Speakers may preview their presentations in the Key Largo Room from 7:00 am to 5:00 pm on Wednesday and Thursday and from 7:00 am to 3:00 pm on Friday.

Coffee Breaks

Complimentary coffee will be served on Tuesday outside the designated Tutorial rooms, and in the Exhibit Hall on Wednesday through Friday.

Hospitality Desk

A hospitality desk will be set up adjacent to the registration area to answer any questions you may have regarding local attractions and events.

Airport/Hotel Transportation

The Orlando International Airport is located about 30 minutes from the Hyatt Orlando Hotel. Shuttle and taxi service is available to and from the hotel. The average taxi fare is \$40 each way. Shuttle service to and from the airport is provided by Mears Transportation. The round trip fare is \$27. For more information, please visit www.mearstransportation.com or call 407/423-5566.

Message Center

Messages for attendees will be posted in the Message Center located adjacent to the IEEE SENSORS registration desk. For incoming messages, please call the Hyatt Orlando at 407/396-1234 and ask to be transferred to the IEEE SENSORS registration desk.

Visa Requests

International participants may need a letter of invitation in order to obtain a visa. Requests should clearly state the participant's full name, full address, fax number, and e-mail address. Requests for invitation letters should be sent to:

IEEE SENSORS 2002 Conference

Attn: Jimmy Le 411 Lafayette Street, Suite 201 New York, NY 10003 Fax: 212/460-5460 e-mail: jle@pcm411.com

Reception and Banquet

All conference attendees are invited to attend the reception scheduled to be held on Tuesday evening, June 11. The reception will accompany the opening of the SENSORS 2002 Exhibition. The reception will begin at 7:00 pm in Florida Hall West. Conference attendees are also invited to attend the Banquet to be held on Thursday evening, June 13. This event promises to be one of the highlights of the conference, allowing the sensors community to meet in a congenial environment. The Banquet will begin at 7:00 pm in Paradise Ballrooms II & III. The banquet speaker will be Dean Kamen, inventor of the Segway[™] Human Transporter. Also, the Best Student Paper Award will be announced.

Paper Awards

The IEEE Sensor 2002 Conference will bestow a Best Paper Award and a Best Student Paper Award. The Best Student Paper Award will be presented at the Thursday evening banquet. The winner will receive a plaque and a cash award of \$1000. The Best Paper Award winner will also receive a plaque and an award of \$1000, but will be announced at the 2003 IEEE SENSORS Conference. Both awards are sponsored by Samsung.

Conference Contact

Anyone requiring additional information should contact the Conference Coordinator, Jimmy Le, c/o Palisades Convention Management, 411 Lafayette Street, Suite 201, New York, NY 10003, 212/460-8090 ext. 208, or jle@ pcm411.com. For registration verification, call 1-800-350-0111 or 212/460-9700.

Conference Web Site

For additional information on Orlando and the IEEE Sensors Conference, individuals are encouraged to visit our Web site at http://www.ieee.org/sensors.

TUESDAY, JUNE 11 TUTORIALS

Tutorials 1-4

SENSORS AND SYSTEMS APPLICATIONS

Tuesday, June 11 / 9:00 am - 5:30 pm / Paradise D&E

Tutorials Chair:

Michiel J. Vellekoop, Technical University of Vienna, Austria

T-1: Technology, Principles, and Applications of Inertial Microelectromechanical Sensors (9:00–10:30)

> Andrei M. Shkel University of California at Irvine, Irvine, CA

Sukhan Lee Samsung Advanced Institute of Technology, Suwon, Korea

This tutorial covers three major topics related to the technology, physics, and applications of micro-scale inertial sensors (accelerometers and gyroscopes). The first part provides a basic introduction to MEMS technology, covering primary questions needed to evaluate micro-machining as a technology of choice for inertial micro-sensors. Three technologies (surface micromachining, bulk micromachining, and mixed fabrication processes) will be introduced and compared. The second part of the tutorial will be devoted to (i) an overview of R&D efforts worldwide; (ii) the introduction to the principles of operation and detection; (iii) a review of the advantages and challenges; and (iv) speculation about possible future design trends. The tutorial micro-sensors and discussing future opportunities for this sensor technology in medicine, robotics, personal navigation, and consumer electronics.

Instructor Bios:

Andrei M. Shkel is an Assistant Professor in the Department of Mechanical & Aerospace Engineering at the University of California, Irvine. He is also the Director of the UCI Micro-Systems Laboratory. Dr. Shkel's research interests are in design, fabrication, packaging, and advanced control of integrated microelectromechanical systems (MEMS) for biomedical, communications, and inertial applications. He served as a reviewer for more than a dozen major journals and international conferences in these areas, published over 40 papers in archival journals and international conferences, and organized/ co-organized several tutorials on MEMS technology and sensors-related symposia, conferences, and special conference sessions. Dr. Shkel is an associate member of the IEEE, ASME, and SPIE.

Sukhan Lee is currently an Executive Vice-President of the Samsung Advanced Institute of Technology (SAIT), Corporate R&D Center, Samsung. He is currently serving as a Chief Research Officer overseeing Micro/Nano Systems Technologies. He is also leading a team for breakthrough research. Prior to joining SAIT in 1998, Dr. Lee has been a Professor of Electrical Engineering and Computer Science at the University of Southern California since 1983. He has also been a Senior Member of the Technical Staff at the Jet Propulsion Laboratory, California Institute of Technology, since 1990. Dr. Lee received his Ph.D. in Electrical Engineering from Purdue University, West Lafayette, Indiana, in 1982, and his M.S. and B.S. degrees in Electrical Engineering from Seoul National University, Korea, in 1972 and 1974, respectively. He has been elected as an IEEE Fellow in 1998, and elected as a Member of Korean National Science of Academy in 1999. He is currently a Vice-President of the Korean Sensor Society and a Vice-President of the Korean Electrical and Electronics Materials Society.

BREAK

(10:10-10:30)

IEEE SENSORS 2002 ORGANIZING COMMITTEE

General Chair: Franco Maloberti, University of Texas at Dallas

General Vice-Chair: Tom Wiener, The Forté Consultancy

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T-2: Electronic Noses: Towards a Smart Nose-on-a-Chip

(11:00-12:30)

Julian W. Gardner University of Warwick, Warick, U.K.

In the first part of this tutorial, an overview of the microtechnologies and signal-processing methods employed in the different types of electronic noses reported to date will be presented. Recent efforts on the development of a smart "nose-on-a-chip" /n i.e., a small micro-machined electronic nose will some level of intelligence /n will be discussed. In the second part of the tutorial, the different types of commercial electronic noses will be reviewed, from the large desktop PC-based systems through small portable, handheld units. Then, the applications of electronic noses will be described from quality assurance in the foods and drink industries through to automotive engineering and more-tentative biomedical diagnostics. Finally, the marketplace for odor sensors and electronic noses will be examined and some thoughts on their successful future potential to disrupt/create mass markets will be presented.

Instructor Bio:

Julian W. Gardner received his B.Sc., Ph.D., D.Sc. CEng., FIEE, and MIEEE degrees. He is a Professor of Electronic Engineering at the School of Engineering of Warwick University. He has worked in the field of microsensors for 15 years and pioneered research in the emerging fields of machine olfaction and electronic noses. Dr. Gardner leads a research group on smart devices and is an author or co-author of over 250 technical papers and patents as well as six technical books, several on electronic noses. Interested readers are referred to "Electronic Noses: Principles and Application," edited by Gardner and Bartlett (Oxford University Press, 1999).

LUN	CH	(12:30-2:00)
T-3:	Optical-Fiber Sensors	(2:00-3:30)

Richard O. Claus Virginia Tech, Blacksburg, VA

Optical-fiber sensors have been developed during the past 25 years for numerous measurement system applications. In many cases, they have distinct performance advantages over conventional sensing approaches for use in harsh environments or where massive sensor multiplexing is required. This tutorial describes the fundamentals of optical-fiber sensors and presents examples of specific uses in both laboratory and field instrumentation applications.

Instructor Bio:

Richard Claus received his B.E.S. and Ph.D. degrees from the Johns Hopkins University in the 1970s. Since 1977, he has served on the engineering faculty at Virginia Tech, where he is currently the Lewis A. Hester Chair of Engineering and the Director of the Fiber- and Electro-Optics Research Center. With colleagues and students, he has authored more than 800 journal and conference papers and 29 issued patents. He has received research awards from SPIE, OSA, ASME, and ASCE for work related to optical-fiber sensors and materials. In 2002, he is serving as the Technical Chair of the Optical Fiber Sensors (OFS) Conference in Portland, Oregon.

BREAK

(3:30-4:00)

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(00:07-01:07)

T-4: Magnetic Sensor Microsystems

Rade S. Popovic Swiss Federal Institute of Technology Lausanne, Lausanne, Switzerland

This tutorial will provide insight into the magnetic sensor microsystems with the highest industrial impact. They are based on Hall, AMR, GMR, inductive, and flux-gate magnetic sensors. A summary of a few relevant basic physical phenomena will begin the tutorial. Then, how we can exploit these phenomena and their combinations in magnetic sensor devices and how we can combine these devices with electronic circuits in order to amplify the useful signal and suppress parasitic influences, such as offset, noise, and temperature effects, will be explained. Finally, some of the successful realizations of the corresponding magnetic sensor microsystems and their applications will be discussed.

(4:00-5:30)

Instructor Bio:

Radivoje S. *Popovic* obtained his Dipl. Ing. degree in engineering physics from the University of Belgrade, and M.Sc. and Dr.Sc. from the University of Nis, Yugoslavia. From 1969 to 1981, he worked for Ei, Nis, Yugoslavia. From 1982 to 1993, he was with Landis & Gyr, Zug, Switzerland, responsible for research in sensor microsystems, and became Vice-President, R&D. Currently, he is a professor for microsystems at the Swiss Federal Institute of Technology Lausanne (EPFL), Switzerland. His interests include sensors for magnetic and optical signals. Mr. Popovic is founder of the magnetic sensor company SENTRON AG, Zug, Switzerland, and is an IEEE EDS Distinguished Lecturer.

ENGINEERING THE SENSORS OF TOMORROW

Tuesday, June 11 / 9:00 am - 5:30 pm / Paradise A&B

T-5: Measurement System Design and Evolution (9:00-10:30)

Patrick L. Walter

Endevco Corp., San Juan Capistrano, CA, and Texas Christian University, Fort Worth, TX

The focus of this tutorial will be on providing guidance to optimize measurement system design. It will first look back at some of the historic beginnings of pressure, force, acceleration, and strain measurements. It then will provide an introduction to the key considerations that should be applied to measurement systems being designed for test and control applications. Rules of thumb that can be applied to data before accepting them as valid for subsequent analyses will also be provided. Lastly, future trends in measurement systems such as MEMS, wireless data transmission, and smart transducers will be covered.

Instructor Bio:

Patrick L. Walter was employed for 30 years at Sandia National Laboratories in Albuquerque, New Mexico. For the majority of this time, he managed various flight, field, and laboratory test activities. In 1995, Dr. Walter joined the Engineering Department of Texas Christian University. Since 1996, he has also performed technical consulting at Endevco Corp. Dr. Walter has numerous publications, has served and chaired DoD and DOE committees, and lectures in measurement system design. He is a member of the Instrument Society of America, Society of Experimental Mechanics, American Society of Engineering Educators (Instrumentation and Design Divisions), and is a licensed professional engineer.

BREAK	(10:30-11:00)

T-6: Low-Offset dc Amplifiers for Sensors (11:00–12:30)

Kofi Makinwa

Delft University of Technology, Delft, The Netherlands

In recent years, several new techniques have been developed to reduce offset in CMOS amplifiers and comparators. New chopping techniques in particular make it possible to reduce amplifier offset to the sub-microvolt level. This tutorial will cover the use of chopping and auto-zeroing in the design of CMOS interface circuitry for sensors. Examples of the use of these techniques in SMART wind, temperature, and magnetic sensors will be given.

Instructor Bio:

Kofi Makinwa studied at the Obafemi Awolowo University, Ile-Ife, Nigeria, where he received his B.S. degree (1st class honors) in 1985 and his M.S. degree in 1988, both in Electronic Engineering. He then proceeded to the Philips International Institute, Eindhoven, The Netherlands, where he received his M.E.E. degree (with distinction) in 1989. He began his working career in 1989 as a research scientist at Philips Research Laboratories in Eindhoven, a position he held till 1999. During this period he developed electronic systems for interactive displays and for optical and magnetic storage systems. He is currently at Delft University of Technology, Delft, The Netherlands, where he is working towards his Ph.D. on 2-D thermal flow sensors. He holds nine patents.

LUNCH

(12:30-2:00)

T-7: Technologies for Sensor and Microsystem (2:00–3:30) Fabrication

Martin A. M. Gijs

Swiss Federal Institute of Technology Lausanne, Lausanne, Switzerland

A good control and mastering of technology always is a prerequisite for the correct functioning of a miniaturized sensor or microsystem. Subsequently, technologies related to the realization of structures in Si, metals, glasses, and polymers will be discussed. For example, microfabrication of Si inertial sensors requires knowledge of chemical vapor deposition (CVD) techniques, lithography, as well as on wet and dry etching. For the realization of metallic sensor microstructures, as present in a magnetic read head, technologies such as electroplating and thin-film sputter deposition are important. Glass is an important material for the realization of microfluidic devices, and various glass etching and bonding technologies will be discussed. Finally, polymers and plastics form a fourth important category of materials. The use of functional thick resists, micromoulding, and high-precision microfabrication of structures using the LIGA technique will be presented.

Instructor Bio:

Martin A. M. Gijs received his B.Sc. degree in physics in 1981 from the Katholieke Universiteit Leuven, Belgium, and his Ph.D. degree in physics at the same university in 1986. He joined Philips Research Laboratories in Eindhoven, The Netherlands, in 1987. Subsequently, he has been working on micro- and nano-fabrication processes of high-critical-temperature superconducting Josephson and tunnel junctions, the microfabrication of microstructures in magnetic multilayers showing the giant magnetoresistance effect, the design and realization of planar transformers for hard-disk applications, and the design and realization of planar transformers for miniaturized power applications. Since 1997, he has been with the Swiss Federal Institute of Technology Lausanne (Ecole Polytechnique Fédérale de Lausanne) as a professor heading the Microsystems. His main interests are in developing new glass and magnetic device microfabrication technologies and the development and use of microsystem technologies for biomedical applications (bio-MEMS).

BREAK

(3:30-4:00)

T-8: Modeling and Simulation: Automatic (4:30–5:30) Model Reduction

Jan G. Korvink and Evgenii Rudnyi University of Freiburg, Freiburg, Germany

The rapid development of MEMS-based devices requires a 3-D timedependent simulation for coupled physical domains (thermal, mechanical, electrical, etc.). This requires a solution of high-dimensional ordinary differential equations (ODEs), resulting from the space discretization of the device, and hence, as a rule, parallel computing. However, instead of a "brute force" approach to integrate a large system of ODEs, one can use modern mathematical methods to reduce its dimension. It happens that in many cases of practical importance the order of ODEs can be reduced by several orders of magnitude, almost without sacrificing precision. During the tutorial, the attendee will learn: (1) How to reduce relatively small linear systems up to 1000 orders of ODEs with SLICOT library, implementing the latest developments of modern control theory; (2) How to employ implicit moment matching methods based on Krylov subspaces (Arnoldi and Lanczos algorithms) to reduce huge linear systems of ODEs; (3) What to expect from mathematicians in the near future in order to be able to apply results from control theory to large linear systems; and (4) How to reduce nonlinear systems of ODEs by means of Proper Orthogonal Decomposition.

Instructor Bio:

Jan G. Korvink holds the chair of microsystem simulation at the University of Freiburg. He received his D.Sc. degree from the Swiss Federal Institute of Technology (ETH) in 1993, and his M.Sc. degree from the University of Cape Town in 1987. Dr. Korvink was senior scientist at the Physical Electronics Laboratory of ETH before moving to Freiburg. He is co-author of more than 40 technical articles in conference proceedings and journals, and has co-authored one book chapter and the SOLIDIS microsystem simulation soft ware. He is co-founder and current chairman of the CAD for MEMS international workshop. He serves on the program selection committees of the IEEE-IEDM and the IEEE-MEMS. Dr. Korvink is the associate editor (Europe) for "Sensors and Materials," MYUKK, Tokyo, Japan. He is a member of the IEEE and the ASME. His main research interests are in the modelling and numeric cal simulation of microsystems.

Keynotes

Session 2

PLENARY SESSION

Wednesday, June 12 / 8:30-10:00 am / Paradise II & III

Chair: Franco Maloberti, University of Texas, USA

Welcoming

(8:30-9:00)

John Vig, Founding President, IEEE Sensors Council Franco Maloberti, President, IEEE Sensors 2002 Michael Shur, Technical Program Co-Chair, IEEE Sensors 2002

Keynote Addresses

1.1: Bio Warfare Defense Sensors: (9:00–9:30) Applications and Research

> Dr. Amy E. Alving, Director, Special Projects Office DARPA, Arlington, VA

Some applications for bio warfare defense sensors and the needs that arise from those applications, as well as some current areas of research and development to meet those needs, will be described.

1.2: New Optical Sensors Fabricated by Si

(9:30-10:00)

Professor Kazuhiro Hane Graduate School of Mechanical Engineering Tohoku University, Miyagi, Japan

Si micromachinig is a promising technique for the fabrication of several optical sensors. It is also indispensable for low-cost assembly. We studied the Si micromaching for the fabrication of optical sensors and optical systems. Deep reactive ion etching (D-RIE) was used to produce the Si three-dimensional structures of the sensors. New versions of the optical position sensor, optical encoder, and laser interferometer were proposed. In those sensors, the optical transmission structures were employed to generate new optical functions. The Si micromachining was also applied to the integration of optical components. The integrated optical systems such as the laser beam scanner and the micro-probe for scanning near-field optical microscopy were fabricated. In the integration, the Si three-dimensional structures were fabricated by a lithographic technique using spray resist coater.

BREAK

(10:00-10:30)

INTEGRATED OPTICAL SENSORS I

Wednesday, June 12 / 10:30 am - 12:00 pm / Ballroom II

Chair: Matthew Clark, University of Nottingham, U.K.

2.1: Invited Paper: Integrated Optical Sensors for (10:30) Active 3-D Vision

> A. Simoni Istituto Trentino di Cultura (ITC-irst), Trento, Italy

2.2: Optical/Electronic "Whisker" Sensors for (11:00) Detecting Airflow, Vibration, and Touch on Mobile Robotic Systems

C. M. Higgins, S. L. Hill University of Arizona, Tucson, AZ

2.3: A Real-Time VLSI Optical Centroid Processor (11:15)

B. H. Pui, B. Hayes-Gill, M. Clark, M. Somekh, C. See, S. Morgan, A. Ng University of Nottingham, Nottingham, U.K.

Integrated Motion-Computation Sensor

(11:30)

M. A. Estrada, E. Turenne, D. Poussart, M. Tremblay Laval University, Quebec, Canada

2.5: A Time-Based Asynchronous Readout CMOS (11:45) CMOS Image Sensor for High-Dynamic Range Application

X. Guo, J. G. Harris University of Florida, Gainesville, FL

LUNCH

2.4:

(12:00-1:30)

An and a second second

10

MOLECULAR SELF-ASSEMBLED SENSORS

Wednesday, June 12 / 10:30 am - 12:00 pm / Ballroom III

Chair: Francisco Arregui, University of Navarra, Spain

3.1: Invited Paper: Molecularly Self-Assembled (10:30) Sensors for Biomedical Applications

> J. B. Mecham, K. Huie NanoSonic, Inc., Blacksburg, VA

Q. Chen Virginia Tech, Blacksburg, VA

R. O. Claus NanoSonic, Inc., Blacksburg, VA, and Virginia Tech, Blacksburg, VA

F. J. Arregui, I. R. Matias Universidad Publica de Navarra, Pamplona, Spain

3.2: Invited Paper: Molecularly Self-Assembled (11:00) Optical-Fiber Sensors

I. R. Matias, F. J. Arregui Universidad Publica de Navarra, Pamplona, Spain

R. O. Claus Virginia Tech, Blacksburg, VA, and NanoSonic, Inc., Blacksburg, VA

K. L. Cooper NanoSonic, Inc., Blacksburg, VA

3.3: Self-Assembled Monolayers of Chiral Porphyrin (11:30) Diads as Sensing Material for Enantioselective Chemical Sensors

R. Paolesse, C. Di Natale, A. Froiio, E. Martinelli University of Rome "Tor Vergata," Rome, Italy

A. Macagnano IME-CNR, Lecce, Italy, and PSM-CNR, Rome, Italy

A. D'Amico University of Rome "Tor Vergata," Rome, Italy; IME-CNR, Lecce, Italy; and PSM-CNR, Rome, Italy

3.4: Humidity-Sensitive Properties of In-Situ Synthesized Sodium Polystyrenesulfonate/ ZnO Nanocomposites

(11:45)

M. J. Yang, Y. Li, Y. She, M. F. Ling, H. P. Wang Zhejiang University, Hangzhou, People's Republic of China

LUNCH

(12:00-1:30)

INNOVATIVE AUTOMOTIVE SENSORS

Wednesday, June 12 / 10:30 am - 12:00 pm / Ballroom A

Chair: Bernhard Jakoby, Technical University of Vienna, Austria

4.1: Invited Paper: Micromachined Sensors for (10:30) Automotive Applications

J. Marek Robert Bosch GmbH, Reutlingen, Germany

4.2: Invited Paper: New Chemical Sensors for (11:00) Automotive Applications

J. H. Visser, S. G. Ejakov, D. Kubinski, M. Parsons, R. E. Soltis Ford Research Laboratory, Dearborn, MI

4.3: Linear Magnetic Position Sensor for Automotive Applications

Z. Liu American Microsystems, Inc., Pocatello, ID

L. Tian Intel Corp., Seattle, WA

J. Parham Bourns, Inc., Ogden, UT

A. B. Frazier Georgia Institute of Technology, Atlanta, GA

4.4: Micromachined Thermal-Conductivity Hydrogen (11:45) Detector for Automotive Applications

M. Arndt Robert Bosch GmbH, Reutlingen, Germany

LUNCH

Session 4

(12:00-1:30)

(11:30)

Special Session

FLEXIBLE SENSORS IN SMART APPLICATIONS

Wednesday, June 12 / 10:30 am - 12:00 pm / Ballroom D

Chair: Thomas Papakostas, Tekscan, Inc., USA

5.1: Invited Paper: Electroactive Polymer Fibers and (10:30) Fabrics for Distributed, Conformable, and Interactive Systems

> D. De Rossi University of Pisa, Pisa, Italy

5.2: Invited Paper: Low-Cost Planar PTF Sensors for (11:00) the Identity Verification of Smartcard Holders

N. J. Henderson, N. M. White University of Southampton, Southampton, U.K.

T. V. Papakostas Tekscan, Inc., Boston, MA

P. H. Hartel Universiteit Twente, Enschede, The Netherlands

5.3: A Large-Area Force Sensor for Smart-Skin (11:30) Applications

> T. V. Papakostas, J. Lima, M. Lowe Tekscan, Inc., Boston, MA

5.4: A Textile-Based Capacitive Pressure Sensor (11:45)

M. Sergio, N. Manaresi, M. Tartagni, R. Guerrieri University of Bologna, Bologna, Italy

R. Canegallo STMicroelectronics, Italy

LUNCH

(12:00-1:30)

HARSH-ENVIRONMENT MICROSYSTEMS AND NANOSYSTEMS TECHNOLOGY I

Wednesday, June 12 / 10:30 am - 12:00 pm / Ballroom C

Co-Chairs:

Session 6

Robert Okojie, NASA–Glenn Research Center, USA Kevin Kornegay, Cornell University, USA

6.1: Invited Paper: Commercialization of Harsh- (10:30) Environment Microsystems: Existing Challenges

> W. C. Merrill Glennan Microsystems Initiative, Cleveland, OH

6.2: Invited Paper: Silicon Carbide for MEMS and (11:00) NEMS: An Overview

> C. A. Zorman, M. Mehregany Case Western Reserve University, Cleveland, OH

6.3: Pt/Ga₂O₃/SiC Schottky-Diode-Based Gas Sensor (11:30)

A. Trinchi, Y. Li, W. Wlodarski RMIT University, Melbourne, Australia

6.4: Interface States in High-Temperature SiC Gas (11:45) Sensing

> R. N. Ghosh, P. Tobias, B. Golding Michigan State University, East Lansing, MI

LUNCH

(12:00-1:30)

SENSORS FOR MICRO-TORQUE MEASUREMENTS

Wednesday, June 12 / 10:30 am - 12:00 pm / Ballroom F

Chair: Werner Brenner, Vienna University of Technology, Austria

7.1: Invited Paper: Microstructure Torque Estimation (10:30) Using MEMS Optical Monitoring

J. Park, L. Wang, J. Dawson, L. Hornak, P. Famouri West Virginia University, Morgantown, WV

7.2: Invited paper: Micro-Torque Measurement (11:00) Using Outer-Rotor Polysilicon Micromotors

K. C. Stark NineSigma, Inc., Hightstown, NJ

A. A. Yasseen Orchid BioSciences, Inc., Princeton, NJ

S. M. Phillips, M. Mehregany Case Western Reserve University, Cleveland, OH

7.3: Invited Paper: Principles of Torque Measurement (11:30) for Rotating Microactuators

> G. Abraham, R. Duffait, P. Wurmsdobler, A. Matzner, W. Brenner MTE Innovative Measurement Solutions Messsysteme GmbH, Vienna, Austria

LUNCH

(12:00-1:30)

INTEGRATED OPTICAL SENSORS II

Wednesday, June 12 / 1:30-3:00 pm / Ballroom II

Chair: Matthew Clark, University of Nottingham, U.K.

Session 8

8.1: Invited Paper: Smart Pixel Arrays for Coherent (1:30) Detection Technologies

> R. P. Salathé, École Polytechnique Fédérale de Lausanne, Lausanne, Switzerland

8.2: A CMOS Smart Pixel for Active 3-D Vision (2:00) Applications

L. Viarani, D. Stoppa, L. Gonzo, M. Gottardi, A. Simoni Istituto Trentino di Cultura (ITC-irst), Trento, Italy

8.3: Experimental High-Speed CMOS Image Sensor (2:15) System and Applications

A. O. Ercan, F. Xiao, X. Liu, S. H. Lim, A. El Gamal, B. Wandell Stanford University, Stanford, CA

8.4: Reconfigurable Vision with High-Performance (2:30) CMOS Active Pixel Sensors

B. Pain, G. Yang, C. Sun, C. Basset, T. Cunningham, C. Wrigley Jet Propulsion Laboratory, California Institute of Technology, Pasadena, CA

8.5: OMNIVIEWS: Direct Omnidirectional Imaging (2:45) Based on a Retina-like Sensor

G. Sandini University of Genoa, Genoa, Italy

T. Pajdla Czech Technical University, Prague, Czechoslovakia

J. Santos-Victor Instituto Superior Tecnico, Lisbon, Portugal

BREAK

(3:00-3:30)

BIOLOGICAL SENSING I

Wednesday, June 12 / 1:30-3:00 pm / Ballroom III

Chair: Dwight Woolard, Army Resaerch Office, USA

9.1: Plastic Colorimetric Resonant Optical Biosensor (1:30) for Multiparallel Detection of Label-Free Biochemical Interactions

B. Cunningham, B. Lin, J. Qiu, P. Li, J. Pepper, B. Hugh SRU Biosystems, Woburn, MA

9.2: Biosensing Using Thickness-Shear-Mode (TSM) (1:45) Quartz Resonators: Viscoelastic Film with Liquid-Overlayer Analysis

C. A. Bailey, B. Fiebor, W. Yan, V. Vodyanoy, R. W. Cernosek, B. A. Chin Auburn University, Auburn University, AL

9.3: Monitoring the Kinetics of Endothelial Cell (2:00) Behavior in Suspensions Using TSM Piezoelectric Sensors

K. A. Barbee, R. M. Lec, J. Sorial Drexel University, Philadelphia, PA

A. Fertala Thomas Jefferson Medical University, Philadelphia, PA

9.4: Electrical-Permittivity-Based Sensor to Evaluate (2:15) Fresh-Milk Somatic-Cell Concentration

G. J. Grillo, M. A. Pérez, J. C. Antón, F. J. Ferrero University of Oviedo, Asturias, Spain

9.5: Surface Biopotential Monitoring by Needle-Type (2:30) Micro Electrode Array

> L. C. Pan Taipei Medical University, Taiwan, R.O.C.

P. W. Lin Taipei Municipal Wan-Fang Hospital, Taiwan, R.O.C.

F. G. Tseng, C. Lin National Tsing Hua University, Taiwan, R.O.C.

9.6: A CMOS-Compatible Optical Filter for High-Throughput Enzymatic-Analysis Devices (2:45)

> V. P. Iordanov, R. Ishihara, P. M. Sarro, A. Bossche Delft University of Technology, Delft, The Netherlands

M. J. Vellekoop Vienna University of Technology, Gusshausstrasse, Austria

BREAK

Session 10

APPLICATIONS: AUTOMOTIVE

Wednesday, June 12 / 1:30-2:45 pm / Ballroom A

Chair: Jiri Marek, Robert Bosch GmbH, Germany

10.1: Touch-Mode Capacitive Pressure Sensor for (1:30) Passive Tire-Monitoring System

> S. Yamamoto, O. Nakao, H. Nishimura, H. Nakamura, T. Takizawa, R. S. Pollack Fujikura, Ltd., Tokyo, Japan

R. S. Pollack Phase IV Engineering

10.2: Microacoustic Viscosity Sensor for Automotive (1:45) Applications

B. Jakoby Vienna University of Technology, Vienna, Austria

M. Scherer, M. Buskies, H. Eisenschmid Robert Bosch GmbH, Reutlingen, Germany

10.3: Vehicle Fault Diagnostics Using a Sensor-Fusion Approach (2:00)

S. Muldoon, M. Kowalczyk, J. Shen Delphi Technical Center-Brighton, Brighton, MI

10.4: Common Design Techniques for Quartz Rate (2:15) Sensors for Both Automotive and Aerospace/ Defense Market Applications

A. M. Madni BEI Technologies, Inc., Sylmar, CA

L. E. Costlow BEI Technologies, Inc., Systron Donner Inertial Division, Concord, CA

10.5: The Investigation of Stator Coil and Lead (2:30) Temperatures on the High Voltage Inside Large Power Generators *via* Use of Fiber Bragg Gratings

N. M. Theune, M. Müller, H. Hertsch, J. Kaiser, M. Willsch, P. Krämmer, T. Bosselmann Siemens AG, Erlangen, Germany

BREAK

(3:00 - 3:30)

(2:45 - 3:30)

SIGNAL PROCESSING I

Wednesday, June 12 / 1:30-3:00 pm / Ballroom D

Chair: Julian Gardner, University of Warwick, Coventry, U.K.

11.1: Selecting Bands for Angle-Based Classification (1:30) in Hyperspectral Processing

N. Keshava, A. Batra MIT Lincoln Laboratory, Lexington, MA

11.2: Sensor Impedance-Spectrum-Measurement (1:45) Interface with Lock-In Amplifier

> S.-Q. Ma, J. Schroeder, P. Hauptmann University of Magdeburg, Magdeburg, Germany

11.3: An Adaptive Fuzzy-Logic Algorithm for Ranking (2:00) Logical Sensory Performance

> G. Shayer, O. Cohen, Y. Edan, E. Korach Ben-Gurion University of the Negev, Beersheba, Israel

11.4: The Assessment of the Final Metrological (2:15) Characteristics of a MEMS-Based NDIR Spectrometer through System Modeling and Data Processing

> C. Calaza, E. Meca, M. Moreno, S. Marco, J. Samitier University of Barcelona, Barcelona, Spain

11.5: Ultrasonic Multi-Transducer Processing for (2:30) Pattern Recognition

> N. Aitoufroukh, E. Colle University of Evry Val d'Essonne, Courcouronnes, France

C. Barat CNRS, Sophia Antipolis, France

11.6: Electronic-Nose Module with System on Chip (2:45)

E.-T. Jang, W.-Y. Chung Dongseo University, Pusan, Korea

BREAK

(3:00-3:30)

1.00

HUMIDITY SENSORS

Wednesday, June 12 / 1:30-3:00 pm / Ballroom C

Chair: Hiroaki Suzuki, University of Tsukuba, Japan

12.1: Novel Soil-Moisture Sensors Applying Thermal (1:30) Characteristics of Soil and Water

> Y. Yamamoto, K. Hamaguchi, Y. Yamamoto, A. Ogawa Tamagawa University, Tokyo, Japan

12.2: High-Sensitivity Low-Relative-Humidity Sensor (1:45) Based on Overlay on Side-Polished Fibers

> A. Álvarez-Herrero, H. Guerrero Instituto Nacional de Técnica Aeroespacial, Madrid, Spain

D. Levy

Instituto Nacional de Técnica Aeroespacial, Madrid, Spain, and Instituto de Ciencia de Materiales de Madrid, Madrid, Spain

12.3: Contributions to the Measured Capacitance by (2:00) the Dielectric Properties of Water in Insulated Electrode Soil-Moisture Sensors

> P. Johnson, D. Thiel, D. James Griffith University, Nathan, Australia

12.4: Relative-Humidity Sensors Based on Porous (2:15) Polysilicon and Porous Silicon Carbide

> E. J. Connolly, H. T. M. Pham, P. M. Sarro, P. J. French Delft University of Technology, Delft, The Netherlands

12.5: Porous Silicon Vapor Sensor with Phase-Detection Electronics (2:30)

H. Saha, J. Das, S. Dey, S. M. Hossain Jadavpur University, Kolkata, India

12.6: A Novel Highly Reversible Humidity Sensor (2:45) Based on Poly(2-propyn-2-furoate)

M. J. Yang, Y. Li, M. F. Ling Zhejiang University, Hangzhou, People's Republic of China

BREAK

(3:00 - 3:30)

SENSOR PHENOMENA

Wednesday, June 12 / 1:30-3:00 pm / Ballroom F

Chair: W. Wlodarski, RMIT University, Australia

13.1: Organic Molecular Thin Films as Gas Sensors (1:30)

L. Lozzi, S. Santucci, M. Passacantando, L. Ottaviano, C. Cantalini University of L'Aquila, L'Aquila, Italy

13.2: Frequency Interference Between Two Quartz-Crystal Microbalances (1:45)

K. H. Lee, F. Shen, P. Lu, S. J. O'Shea Institute of High Performance Computing, The Rutherford, Singapore

13.3: Energy Trapping in Mesa-Shaped Quartz-Crystal Microbalance (2:00)

F. Shen, K. H. Lee, P. Lu, S. J. O'Shea Institute of High Performance Computing, The Rutherford, Singapore

13.4: Planar Anti-Resonant Reflecting Optical Waveguides as Sensors for Liquid Substances (2:15)

R. Bernini CNR-IREA, Napoli, Italy

S. Campopiano, L. Zeni Seconda Università di Napoli, Aversa, Italy

C. R. de Boer, P. M. Sarro Delft University of Technology, Delft, The Netherlands

13.5: LGX Pure Shear-Horizontal SAW for Liquid (2:30) Sensor Applications

M. Pereira da Cunha University of Maine, Orono, ME

D. C. Malocha University of Central Florida, Orlando, FL

13.6: Refractive-Index Measurements and Their (2:45) Application to Smart Polymer Processing

A. Cusano, G. Breglio, M. Giordano, L. Nicolais University of Naples, Naples, Italy

BREAK

(3:00-3:30)

Session 14

CHEMICAL SENSING I

Wed	nesday, June 12 / 3:30–5:00 pm / Ballroom II	
Chair	: John Vetelino, University of Maine, USA	
14.1:	An Optical Gas Sensor Based on Ellipsometric Readout	(3:30)
	G. Wang, H. Arwin, R. Jansson Linköping University, Linköping, Sweden	
14.2:	Investigation of an Integrated Gas Sensor Array	(3:45)
	GZ. Yan Peking University, Beijing, China, and Hong Kong University of Science & Technology, Hong Kong, Chin	a
	P. C. H. Chan, J. K. O. Sin, IM. Hsing Hong Kong University of Science & Technology, Hong Kong, China	
	M. Miao Peking University, Beijing, China	
14.3:	Electronic Interface Modules for Solid-State Chemical Sensors	(4:00)
	S. McKennoch, D. M. Wilson University of Washington, Seattle, WA	
14.4:	A Single-Chip pH Sensor Fabricated by a Conventional CMOS Process	(4:15)
	P. A. Hammond, D. R. S. Cumming University of Glasgow, Glasgow, U.K.	
	D. Ali Philips Research Laboratories, Redhill, U.K.	
14.5:	Investigation of Si/LaF ₃ Structure as Light- Addressable Potentiometric Fluoride Sensor	(4:30)
	A. B. M. Ismail Osaka University, Osaka, Japan, and Rajshahi Univer Rajshahi, Bangladesh	sity,
	K. Furuichi, T. Yoshinobu, H. Iwasaki Osaka University, Osaka, Japan	
14.6:	A Novel MEMS Biochemical Sensor Based on Optical Fabry-Perot Interference	(4:45)
	D. Li, S. Jin Tianjin University, Tianjin, People's Republic of China	
	W. Wu, Y. Hao Peking University, Beijing, People's Republic of China	

BIOLOGICAL SENSING II

Wednesday, June 12 / 3:30-5:00 pm / Ballroom III

Chair: Michiel Vellekoop, Technical University of Vienna, Austria

15.1: Comparing Biosensors

(3:30)

L. Lading Sensor Technology Center, Brøndby, Denmark

L. B. Nielsen Biotechnological Institute, Denmark

T. Sevel FORCE Technology, Denmark

15.2: A Cheap and Portable Sensing System for (3:45) Electrochemical Genotyping

S. Cho, J. J. Pak Korea University, Seoul, Korea

15.3: Validation and Benchmarking of a High-Speed (4:00) Modulation Design for Oxygen-Saturation Measurement Using Photoplethysmographic Ring Sensors

P. Shaltis, S. Rhee, H. Asada MIT, Cambridge, MA

15.4: Fabrication and Testing of a Smart Tongue (4:15) Device for Liquid Sensing

M. Cole, G. Sehra, J. W. Gardner University of Warwick, Coventry, U.K.

V. K. Varadan Pennsylvania State University, State College, PA

15.5: QCM Viscometer for Bioremediation Monitoring (4:30)

W. A. Gee, K. M. Ritalahti, W. D. Hunt, F. E. Loeffler Georgia Institute of Technology, Atlanta, GA

15.6: A Miniaturized Planar Glucose Sensor Based on (4:45) Prussian Blue as Electrocatalyst for H₂O₂

J. Zhu, Z. Zhu, Z. Lai East China Normal University, Shanghai, China

FIBER BRAGG GRATINGS IN SENSING SYSTEMS

Wednesday, June 12 / 3:30-5:00 pm / Ballroom A

Chair: Yinian Zhu, Nanyang Technological University, Singapore

16.1: Invited Paper: Advances in UV-Inscribed Fiber-Grating Optical-Sensor Technologies (3:30)

L. Zhang Aston University, Birmingham, U.K.

16.2: Invited Paper: Fabrication and Performance (4:00) Characteristics of Optical Fiber Gratings for Sensing Applications

Y. Chung, U.-C. Paek Kwangju Institute of Science & Technology, Kwangju, Korea

16.3: Dynamic MEMS-Based Photonic Bandgap Filter (4:30)

R. H. Trimm, E. J. Tuck, G. Tuck, M. C. Buncick AEgis Technologies Group, Inc., Huntsville, AL

M. Kranz Morgan Research Corp., Huntsville, AL

P. Reiner Jaycor, Inc., Huntsville, AL

M. G. Temmon, P. R. Ashley U.S. Army and Missile Command, Redstone Arsenal, AL

16.4: Fabrication of Extremely Short-Length Fiber (4:45) Bragg Gratings for Sensor Applications

M.-C. Wu, R. S. Rogowski, K. K. Tedjojuwono NASA Langley Research Center, Hampton, VA

SIGNAL PROCESSING II

Wednesday, June 12 / 3:30-5:00 pm / Ballroom D

Chair: Michael Shur, Rensselaer Polytechnic Institute, USA

17.1: Uncertainty Reduction in an Ultrasonic Pulse-Echo Sensor by Using Full Bandwidth (3:30)

J. A. van Deventer Luleå University of Technology, Luleå, Sweden

17.2: Pre-processing of Electronic-Nose Data by (3:45) Independent Component Analysis

E. Martinelli, C. Falconi, A. D'Amico, C. Di Natale University of Rome, Rome, Italy

17.3: Noise Reduction from Photoplethysmographic (4:00) Measurements Using a Variable Step-Size LMS Filter and an Optoelectronic Sensor

K. W. Chan, Y. T. Zhang The Chinese University of Hong Kong, Shatin, Hong Kong, China

17.4: Velocity Measurement in a Fluid Using LDV: (4:15) Low-Cost Sensor and Signal-Processing Design

A. Le Duff, G. Plantier École Supérieure d'Électronique de L'Ouest, Angers, France

J.-C. Valière Université de Poitiers, Poitiers, France

T. Bosch ENSEEIHT, Toulouse, France

17.5: A Novel Sensor Interrogation Technique Using (4:30) a Chirped Fiber-Grating-Based Sagnac Loop

> D. Zhao, X. Shu, L. Zhang, I. Bennion Aston University, Birmingham, U.K.

17.6: A 66-dB Dynamic Magneto-Optic Current (4:45) Transformer with Advanced Signal Processing

S. Mohr, T. Bosselmann Siemens AG, Erlangen, Germany

Session 18

ACOUSTIC SENSING

Wednesday, June 12 / 3:30-5:00 pm / Ballroom C

Chair: Sub Reddy, University of Surrey, U.K.

18.1: A MEMS Phased-Array Transducer for Ultrasonic (3:30) Flaw Detection

> A. Jain, D. W. Greve, I. J. Oppenheim Carnegie Mellon University, Pittsburgh, PA

18.2: A Novel SAW Micro-Array Concept for Environmental Organic Gas Detection at Low Concentrations

> M. Rapp, F. Bender, A. Voigt Forschungszentrum Karlsruhe GmbH, Karlsruhe, Germany

18.3: Passive Acoustic Sensing for Tracking Knocks (4:00) on Large Interactive Displays

J. A. Paradiso, C. K. Leo, N. Checka, K. Hsiao MIT Media Laboratory, Cambridge, MA

18.4: Detection and Sizing of Micro Bubbles in (4 Streaming Fluids with Ultrasound

(4:15)

(3:45)

K. V. Jenderka Martin Luther University Halle-Wittenberg, Halle, Germany

M. Schultz, G. Dietrich Company for Applied Medical Physics and Technique, Ltd., Germany

18.5: Object-Discrimination System Using a Neural (4:30) Network with Inputs for Distance and Sensitivity Information of an Ultrasonic Sensor

S. Aoshima, N. Yoshizawa, T. Yabuta, K. Hanari Ibaraki University, Ibaraki, Japan

18.6: Wireless, Batteryless, Wearable Microphones (4:45) Using Inductive Coupling

> K. J. Cho, H. H. Asada MIT, Cambridge, MA

Poster Session

INERTIAL SENSORS I

Wednesday, June 12 / 3:30-5:00 pm / Ballroom F

Chair: Qing-An Huang, South East University, China

19.1: A Sensitive and Economical Method to Directly (3:30) Detect Particles

M. A. Cooper, F. N. Dultsev, T. Minson, V. P. Ostanin, C. Abell, D. Klenerman University of Cambridge, Cambridge, U.K.

19.2: Motion-Dynamics Sensing Scheme for MEMS (3:45) Micro-Motor

M. J. McCaslin, E. J. Kozubal Read-Rite Corp., Fremont, CA

M. Del Sarto STMicroelectronics, San Jose, CA

19.3: Monolithic Miniaturized Quartz Microbalance (4:00) Array and Its Application to Chemical Sensor Systems for Liquids

> J. Rabe, S. Büttgenbach Technical University of Braunschweig, Braunschweig, Germany

J. Schröder, P. Hauptmann Otto von Guericke University, Magdeburg, Germany

19.4: A High-Performance Mixed Micromachined (4:15) Differential Resonant Accelerometer

> S. Seok, B. Lee, J. Kim, K. Chun Seoul National University, Seoul, Korea

19.5: Stress-Free Quad-Beam Optical Silicon (4:30) Accelerometer

> J. A. Plaza, A. Llobera, C. Dominguez, J. Esteve Centro Nacional de Microelectrónica, Barcelona, Spain

J. Berganzo, J. Garcia Ikerlan, Spain

19.6: Theoretical Study, Modeling, and Realization of (4:45) Resonant Gyroscopes with Optical Output

S. Baglio, S. Castorina, N. Savalli University of Catania, Catania, Italy

POSTER SESSION I

Wednesday, June 12 / 5:30-7:00 pm / Florida East Hall

INTEGRATED OPTICAL SENSORS

P1.1: Dynamic Particle-Shape Measurements Using a Near-Field Optical Sensor

> J. H. Nieuwenhuis, M. J. Vellekoop Vienna University of Technology, Vienna, Austria

J. Bastemeijer, A. Bossche Delft University of Technology, Delft, The Netherlands

P1.2: Pixel-Based Random Access Image Sensor Array for Real-Time IBR

> R. Oi, K. Aizawa University of Tokyo, Tokyo, Japan

T. Hamamoto Tokyo University of Science, Tokyo, Japan

P1.3: CMOS Passive Pixel Design Techniques

I. L. Fujimori, C. G. Sodini MIT, Cambridge, MA

P1.4: ASIC Design of a SMART Sensor Based on Porous Silicon Sensing

> H. Saha, S. Dey, J. Das, S. M. Hossain Jadavpur University, Kolkata, India

P1.5: Surface-Acoustic-Wave Wavefront Sensor Using Custom Optics on a Standard CMOS Process

> S. D. Sharples, M. Clark, M. G. Somekh University of Nottingham, Nottingham, U.K.

P1.6: Comparison of Different Control-Loop Concepts for Direct Distance Measurement Using Photonic Mixing Devices

> D. Becker, P. Gulden, M. Vossiek Siemens AG, Munich, Germany

P1.7: DOPCAM: Full-Field Laser-Doppler Blood-Flow Imaging

C. Kongsavatsak, S. P. Morgan, B. R. Hayes-Gill, M. Clark, J. A. Crowe University of Nottingham, Nottingham, U.K.

OPTICAL IMAGING PROPERTIES

P1.8: A Spaceborne Multispectral Image Sensor and Performance Tracking

W-S. Lin, W-H. Sung National Taiwan University, Taipei, Taiwan, R.O.C.

P1.9: Fundamental Imaging Properties of Transillumination Laser CT Using Optical Fiber Applicable to Bio-Medical Sensing

Y. Sasaki, J. Suzuki, M. Takagi, T. Yuasa, B. Devaraj, T. Akatsuka Yamagata University, Yamagata, Japan

S. Tanosaki I.T. Research, Co., Ltd., Sendai, Japan

H. Taniguchi Iwate University, Morioka, Japan

P1.10: A New CMOS Pixel with Lateral and Vertical BJT Structure

Y-J. Kook, Y-J. Park, H-S. Min Seoul National University, Seoul, Korea

J-H. Lee Wonkwang University, Jeonbuk, Korea

P1.11: Novel Micro-Scanner for Optical Communications: Architecture and Performance

> D. Yan, B. Xu, J. Castracane University at Albany-SUNY, Albany, NY

P1.12: Comparison of Modern CCD and CMOS Image Sensor Technologies and Systems for Low-Resolution Imaging

B. Carlson Symbol Technologies, Inc., Holtsville, NY

P1.13: A Matrix Transform Imager and Architecture

P. Hasler, A. Bandyopadhyay Georgia Institute of Technology, Atlanta, GA

OPTICAL/PHOTONIC

P1.14: Accurate-Temperature Sensor System Based on Linear-Cavity Fiber Laser Array

> P-C. Peng, H-Y. Tseng, S. Chi National Chiao-Tung University, Hsinchu, Taiwan, R.O.C.

P1.15: Growth and Photoconductor Properties of HgCdTe/GaAs Epilayers

K. J. Hong, C. S. Park Chosun University, Kwangju, Korea

P1.16: Limitary Operation Conditions Affecting CID Near-Infrared Detector Performance

> B. G. Vainer Institute of Semiconductor Physics, Novosibirsk, Russia

P1.17: Integrated 2-D Optical Lenses Designed in PDMS Layer to Improve Fluorescence Using Optical Fibers

S. Camou, T. Fujii, J-P. Gouy, H. Fujita University of Tokyo, Tokyo, Japan

P1.18: Novel Microactuators Based on a Photo-Thermo-Mechanical Actuation Strategy

S. Baglio, S. Castorina, L. Fortuna, N. Savalli University of Catania, Cantania, Italy

P1.19: Preparation of Nanocrystalline CdS by Novel Microwave Solvothermal Technique for Photonic Applications

> A. V. Murugan, B. B. Kale, R. S. Sonawane Centre for Materials for Electronics Technology, Pune, India

V. Saaminathan Multimedia University, Selangor, Malaysia

ACOUSTIC

P1.20: Novel QCM Biosensing Based on Analyte-Specific Precipitation Reactions

> S. M. Reddy, N. G. Karousos University of Surrey, Surrey, U.K.

P1.21: Novel MEMS Microshell Transducer Arrays for High-Resolution Underwater Acoustic Imaging Applications

M. Mescher, K. Houston Charles Stark Draper Laboratory, Cambridge, MA

J. Bernstein Corning, Inc., Corning, NY

L. E. Cross, B. Xu, J. Cheng The Pennsylvannia State University, University Park, PA

IONIZATION RADIATION SENSORS

P1.22: Gamma-Radiation Dosimetry Using Tellurium Dioxide Thin-Film Structures

> K. Arshak, O. Korostynska University of Limerick, Limerick, Ireland

P1.23: Development of a Novel Ultra-Fast Scintillator with MQW Structure

K. Shibuya, M. Koshimizu, K. Asai The University of Tokyo, Tokyo, Japan, and Japan Science and Technology Corp., Saitama, Japan

H. Shibata The University of Tokyo, Tokyo, Japan

P1.24: X-Ray Microdetectors Based on an Array of Scintillators: A Maskless Process Using Laser Ablation

J. G. Rocha, N. F. Ramos, M. V. Moreira, S. Lanceros-Mendez, J. H. Correia University of Minho, Guimaraes, Portugal

R. F. Wolfenbuttel Delft University of Technology, Delft, The Netherlands

P1.25: Multiple-Channel Optical-Fiber Radiation Dosimeter for Radiotherapy Applications

A. L. Huston, P. L. Falkenstein, B. L. Justus Naval Research Laboratory, Washington, DC

R. Altemus, R. W. Miller, H. King National Cancer Institute, National Institutes of Health, Bethesda, MD

MECHANICAL PROPERTIES INERTIAL

P1.26: Design Optimization of Three-Axis Accelerometers Based on Four Seismic Masses

> H. Rödjegärd, G. Anderson The IMEGO Institute, Göteborg, Sweden

MICROWAVE/MILLIMETER-WAVE SENSORS

P1.27: An Ultra-Wideband Radar for Vehicle Detection in Railroad Crossings

> S. P. Lohmeier, R. Rajaraman, V. C. Ramasami University of Kansas, Lawrence, KS

AUTOMOTIVE

P1.28: UV Laser-Diode Fluorescence Fiber Sensor for Commercial Gasolines

K. Ozanyan, T. L. Yeo, H. Hindle, H. McCann University of Manchester, Manchester, U.K.

N. R. J. Poolton University of Manchester, Manchester, U.K., and Daresbury Laboratory, Warrington, U.K.

BIOSENSORS

P1.29: Characterization of Cell Adhesion by the Quartz-Crystal Microbalance Technique

D. Le Guillou-Buffello, M. Gindre, L. Haïder, P. Laugier Universitè de Cergy-Pontoise, Cergy, France

P1.30: Remote System for Patient Monitoring Using Bluetooth™

J. Andreasson, M. Ekström, A. Fard, J. Garcia Castaño, T. Johnson Mälardalen University, Mälardalen, Sweden

P1.31: An Intelligent Optical-Fiber-Based Sensor System for Monitoring Food Quality

M. O'Farrell, E. Lewis University of Limerick, Castletroy, Limerick, Ireland

N. Jackman Echo Food Systems, Limerick, U.K.

P1.32: A Disposable Membrane-Strip Immunosensor

Z. Muhammad-Tahir, E. C. Alocilja Michigan State University, East Lansing, MI

P1.33: A Miniaturized Planar Glucose Sensor Based on Prussian Blue as the Electrocatalyst for H₂O₂

J. Zhu, Z. Zhu, Z. Lai East China Normal University, Shanghai, China

P1.34: Thermal Fluid-Layer Characterization in Microfluidic Systems

H. Ernst Albert-Ludwigs University, Freiburg, Germany, and HSG-IMIT, Villingen-Schwenningen, Germany

G. Urban Albert-Ludwigs University, Freiburg, Germany

P1.35: Fluxgate Can Replace SQUID for Lung Diagnostics

P. Ripka, P. Kaspar, A. Tipek Czech Technical University, Czech Republic

K. Svabova Prague Public Health Center, Prague, Czech Republic

R. Holusa National Institute of Public Health, Czech Republic

P1.36: High-Speed Scanning Wavelength-Multiplexed Fiber-Optic Sensors for Biomedicine

Z. Yaqoob, N. A. Riza University of Central Florida, Orlando, FL

P1.37: Characterization of Protein Films Using the Scanning Kelvin Probe Technique

D. C. Hansen Princeton Applied Research, Oak Ridge, TN

P1.38: Detection of Agricultural Chemicals Using a Lipid Membrane Sensor

Y. Naito Anritsu Corp., Kanagawa, Japan, and Kyushu University, Japan

H. Ikezaki, A. Taniguchi Anritsu Corp., Kanagawa, Japan

K. Toko Kyushu University, Japan

P1.39: Vapor-Phase SAW Immunoassay Sensors

D. D. Stubbs, W. D. Hunt, S. H. Lee, D. F. Doyle Georgia Institute of Technology, Atlanta, GA

ENVIRONMENTAL

P1.40: A Large-Scale Seismic Sensing Array on the Sea Floor with Fiber-Optic Accelerometers

Y. Shindo, T. Yoshikawa Oki Electric Industry Co., Ltd., Shizuoka, Japan

P1.41: Self-calibrated PTC Air-Flow Sensor

M. Horn, L. Umar University of Bundeswehr Munich, Neubiberg, Germany

P1.42: PC-Based Optical Ozone Monitor Using a CCD Photodetector

W-Y. Chung Dongseo University, Pusan, Korea

HUMIDITY

P1.43: Liquid Sensor System Using Reflecting Surface-Acoustic-Wave Delay Lines

> T. Nomura, A. Saitoh Shibaura Institute of Technology, Tokyo, Japan

P1.44: Improvement of Polyimide Capacitive Humidity Sensor by Reactive Ion Etching and Novel Electrode Design

> J. H. Chen, Y. L. Yang, S. R. S. Huang National Tsing Hua University, Hsinchu, Taiwan, R.O.C.

FOOD

P1.45: Sensory and Electronic Nose Analysis of Porcine Meatloaf in Relation to Ingredient Quality

> T. Hansen, D. V. Byrne The Royal Veterinary and Agricultural University, Frederiksberg, Denmark

K. Boholt Teknik Energy & Environment, Søborg, Denmark

E. Gammelgaard Tulip International, Vejle, Denmark

THURSDAY, JUNE 13

Session 20

Special Session

MICROFABRICATED CHEMICAL AND BIOLOGICAL SENSORS I

Thursday, June 13 / 8:30-10:00 am / Ballroom II

Chair: Bahram Ghodsain, Molecular Reflections, Inc., USA

20.1: Invited Paper: Sensor Technologies to Advance (8:30) Genomics Research

> J. A. Schloss National Human Genome Research Institute, National Institutes of Health, Bethesda, MD

20.2: Invited Paper: MEMS-Based Systems for DNA (9:00) Sequencing and Forensics

> D. Ehrlich, L. Carey, J. Chiou, S. Desmarais, S. El-Difrawy, L. Koutny, R. Lam, P. Matsudaira, B. Mckenna, L. Mitnik-Gankin, T. O'Neil, M. Novotny, A. Srivastava, W. Timp MIT, Cambridge, MA

20.3: Electronic Baseline Suppression for Liquid-Conductivity Detection in a Capillary Electrophoresis Microchip (9:30)

> F. Laugere, J. Bastemeijer, A. Bossche Delft University of Technology, Delft, The Netherlands

M. J. Vellekoop Vienna Institute of Technology, Vienna, Austria

20.4: A New Microchannel Device for Protein Detection (9:45) from a Mixture

> Y. Kuo, H. H. Lee Texas A&M University, College Station, TX

BREAK

(10:00-10:30)

Session 21

DEVELOPMENTS IN QUARTZ-CRYSTAL BIOSENSING

Thursday, June 13 / 8:30-10:00 am / Ballroom III

Chair: Sub Reddy, University of Surrey, U.K.

21.1: Invited Paper: Protein Surface Adsorption (8:30) Detected by Magnetic Direct Excitation of Acoustic Waves

M. Thompson, S. Ballantyne University of Toronto, Toronto, Ontario, Canada

21.2: Invited Paper: Kinetic Studies of Molecular (9:00) Recognition on DNA by Using a 27-MHz Quartz-Crystal Microbalance

Y. Okahata Tokyo Institute of Technology, Yokohama, Japan

21.3: Invited Paper: Immobilization of Proteins and (9:30) Oligonucleotides on Gold and Development of Reliable QCM Biosensors

M. Mascini, S. Tombelli Università degli Studi di Firenze, Florence, Italy

BREAK

(10:00-10:30)

INTEGRATED SOI SENSORS I

Thursday, June 13 / 8:30-10:00 am / Ballroom A

- Chair: Adrian M. Ionescu, Ecole Polytechnique Federale de Lausanne, Switzerland
- 22.1: Invited Paper: Silicon-on-Insulator CMOS Gas (8:30) Sensors

F. Udrea, J. W. Gardner University of Cambridge and University of Warwick, Coventry, U.K.

22.2: Invited Paper: Capacitive Pressure and Inertial (9:00) Sensors by Epi-SOI Surface Micromachining

S. Renard, C. Pisella, J. Collet, V. Gaff, J.-L. Lauront Tronic's Microsystems, Grenoble, France

22.3: A Novel Resistive Gas Sensor with Integrated (9:30) MOSFET Micro Hot Plate Based on a SOI CMOS Analog Process

F. Udrea, C. C. Lu, J. A. Covington, J. W. Gardner University of Cambridge and University of Warwick, Coventry, U.K.

22.4: SOI-CMOS Compatible Low-Power Microheater (9:45) Optimization and Fabrication for Smart Gas Sensor Implementations

J. Laconte, C. Dupont, A. Akheyar, J.-P. Raskin, D. Flandre Université Catholique de Louvain, Louvain-la-Neuve, Belgium

BREAK

(10:00-10:30)

TACTILE SENSORS FOR ROBOTICS APPLICATIONS

Thursday, June 13 / 8:30-10:00 am / Ballroom D

Chair: Chiang Liu, University of Illinois at Urbana-Champaign, USA

23.1: Invited Paper: A Tactile Sensory-Enhanced (8:30) Assistive Robot

N. J. Ferrier, C. Lozano, M. Tyler University of Wisconsin at Madison, Madison, WI

23.2: Invited Paper: A Sheet-Type Sensor Using (9:00) Pressure-Conductive Rubber with Electrical-Wire Stitches Method

M. Shimojo, R. Makino The University of Electro-Communications, Tokyo, Japan

A. Namiki, M. Ishikawa, T. Suzuki, K. Mabuchi University of Tokyo, Tokyo, Japan

23.3: Tactile Sensor Based on Piezoelectric Resonance (9:30)

G. M. Krishna, K. Rajanna, L. Shivalingappa Indian Institute of Science, Bangalore, India

23.4: Novel Sensor Technology for Shear and Normal (9:45) Strain Detection with Generalized Electrostriction

T. R. Filanc-Bowen, G. H. Kim, Y. M. Shkel University of Wisconsin at Madison, Madison, WI

BREAK

Session 23

(10:00-10:30)

Session 25

HARSH-ENVIRONMENT MICROSYSTEMS AND NANOSYSTEMS TECHNOLOGY II

Thursday, June 13 / 8:30-10:00 am / Ballroom C

Co-Chairs:

Robert Okojie, NASA–Glenn Research Center, USA Kevin Kornegay, Cornell University, USA

24.1: Invited Paper: Chemical Sensor Arrays for Harsh (8:30) Environments and Aerospace Applications

G. W. Hunter, P. G. Neudeck NASA–Glenn Research Center, Cleveland, OH

D. Makel Makel Engineering, Inc., Chico, CA

C. C. Liu, B. Ward, Q. H. Wu Case Western Reserve University, Cleveland, OH

V. Thomas Ohio Aerospace Institute, Cleveland, OH

24.2: Invited Paper: Characterization of Silicon Carbide (9:00) MEMS for High-g Launch Applications

G. L. Katulka Army Research Laboratory, Aberdeen Proving Ground, MD

24.3: Invited Paper: Packaging Considerations for (9:30) Very-High-Temperature Microsystems

> E. Savrun Sienna Technologies, Inc., Woodinville, WA

BREAK

(10:00-10:30)

INERTIAL SENSORS II

Thursday, June 13 / 8:30-9:45 am / Ballroom F

Chair: Qing-An Huang, South East University, China

25.1: Arrow-Based Optical Accelerometers

(8:30)

A. Llobera, J. A. Plaza, J. Esteve, C. Dominguez Centro Nacional de Microelectrónica, Barcelona, Spain

I. Salinas Universidad de Zaragoza, Zaragoza, Spain

J. Berganzo, J. Garcia Ikerlan, Spain

25.2: Sub-Micron-Range Thickness Measurements (8:45) Using a Novel Scanning Heterodyne Optical Interferometer

N. A. Riza, M. A. Arain University of Central Florida, Orlando, FL

25.3: A Reliable Gyroscope-Based Gait-Phase (9:00) Detection Sensor Embedded in a Shoe Insole

I. P. I. Pappas, S. Mangold Automatic Control Laboratory, Zurich, Switzerland

T. Keller ParaCare Institute for Rehabilitation and Research at University Hospital Balgrist, Zurich, Switzerland

25.4: Feedforward Control Algorithm for Structural-Imperfection Compensation in MEMS Rate-Integrating Gyroscopes

> C. C. Painter, A. M. Shkel University of California at Irvine, Irvine, CA

25.5: Simulation of Characteristic of Comb-Gimbal (9:30) Micromachined Gyroscope

> L. Che, B. Xiong, Y. Wang Shanghai Institute of Microsystem and Information Technology, Chinese Academy of Science, Shanghai, People's Republic of China

BREAK

(9:45-10:30)

MICROFABRICATED CHEMICAL AND BIOLOGICAL SENSORS II

Thursday, June 13 / 10:30 am - 12:00 pm / Ballroom II

Chair: Bahram Ghodsain, Molecular Reflections, Inc., USA

26.1: A Silicon-Based FPW Sensor-Array System (10:30) with Polymer Fluidics Integrated on a PCB

> C. Dubé, J. Fiering, M. Mescher Charles Stark Draper Laboratory, Cambridge, MA

26.2: Magnetic Sensing for Genomic Detection and (10:45) Analysis

> C. R. Tamanaha Geo-Centers, Inc., Fort Washington, MD

R. J. Colton, M. M. Miller, S. P. Mulvaney, J. C. Rife, L. J. Whitman Naval Research Laboratory, Washington, DC

M. A. Piani Nova Research, Inc.

26.3: Advanced Sensor Technologies for Microscale (11:00) to Nanoscale Biological Measurements

D. M. Porterfield University of Missouri-Rolla, Rolla, MO

26.4: A Lab-on-a-Chip for Cell Detection and (11:15) Manipulation

> G. Medoro, N. Manaresi Silicon Biosystems S.R.L, Bologna, Italy

A. Leonardi, L. Altomare, M. Tartagni, R. Guerrieri University of Bologna, Bologna, Italy

26.5: An Optical Sensor for Multi-Component (11:30) Immunodetection

S. Suzuki, Y. Kanakogi, T. Hagiwara, I. Tachibana, M. Iida Siekei University, Tokyo, Japan

26.6: Study of Dual-Parameter Piezoelectric DNA (11:45) Sensor for Liquid Detection

Z. Gao, F. Chao, H. Wang, Y. Fang Tianjin Institute of Hygiene and Environmental Medicine, Tianjin, People's Republic of China

H. Pan, H. Zhu Tsinghua University, Beijing, People's Republic of China

LUNCH

(12:00-1:30)

BIOSENSING III

Thursday, June 13 / 10:30 am - 12:00 pm / Ballroom III

Chair: R. Claus, NanoSonic, Inc., USA

27.1: Optimization of On-Chip Micro-Electromagnets (10:30) for Biomolecular Separation

> Q. Ramadan, D. P. Puiu Nanyang Technological University, Singapore

V. Samper, P. Neuzil Institute of Microelectronics, Singapore

L. Marie, L. T. Meng, H. C. Kiat, Y. S. Qin National University of Singapore, Singapore

27.2: Monitoring Interfacial Biological Processes: (10:45) Deposition of Collagen on Gold Surface with the Use of TSM Piezoelectric Sensors

A. Fertala Thomas Jefferson Medical University, Philadelphia, PA

R. M. Lec Drexel University, Philadelphia, PA

27.3: Microcantilever Sensors for the Detection of (11:00) Biomolecular Interactions

K. M. Hansen, T. G. Thundat Oak Ridge National Laboratory, Oak Ridge, TN

27.4: Development of Life-Cell-Based Affinity (11:15) Microassay for HT Screening

> E. Spiller, T. Frömmichen, A. Zimmermann, A. E. Sippel, G. A. Urban University of Freiburg, Freiburg, Germany

27.5: Photon-Based Sensing of Pathogens in Food (11:30)

F. P. Mathew, E. C. Alocilja Michigan State University, East Lansing, MI

27.6: Fiber-Optic Sensors for Ultrasonic Virtual (11:45) Biopsy

L. Masotti, E. Biagi, A. Acquafresca, D. Menichelli University of Florence, Florence, Italy

LUNCH

(12:00-1:30)

INTEGRATED SOI SENSORS II

Thursday, June 13 / 10:30 am - 12:00 pm / Ballroom A

Chair: Adrian Ionescu, Ecole Polytechnique Federale de Lausanne, Switzerland

28.1: Invited Paper: SOI CMOS Hall-Effect Sensor (10:30) Architectures for High-Temperature Applications up to 300°C

L. Portmann, H. Ballan, M. Declercq Swiss Federal Institute of Technology, Lausanne, Switzerland

28.2: Invited Paper: Intelligent SOI CMOS Integrated (11:00) Circuits and Sensors for Heterogeneous Environments and Applications

D. Flandre, S. Adriaensen, A. Afzalian, J. Laconte, D. Levacq, C. Renaux, L. Vancaillie, J.-P. Raskin Université Catholique de Louvain, Louvain-la-Neuve, Belgium

L. Demeûs, P. Delatte, V. Dessard, G. Picun CISSOID, Louvain-la-Neuve, Belgium

28.3: Design and Fabrication of a Bulk-Silicon (11:30) CMOS-MEMS Gyroscope

> H. Xie, G. K. Fedder Carnegie Mellon University, Pittsburgh, PA

28.4: Ultra-Low-Power Thermal Sensor with Siliconon-Insulator Structure for High-Temperature Applications

B. Li, B. Y. Liu, X. R. Zheng South China University of Technology, Guangzhou, China

P. T. Lai, Z. H. Wu The University of Hong Kong, Hong Kong, China

J. K. O. Sin The Hong Kong University of Science & Technology, Hong Kong, China

LUNCH

(12:00-1:30)

SIGNAL PROCESSING III

Thursday, June 13 / 10:30 am - 12:00 pm / Ballroom D

Chair: Michael Shur, Rensselaer Polytechnic Institute, USA

29.1: Fast Interface for a Resistive Touch Screen (10:30)

R. N. Aguilar, G. C. M. Meijer Delft University of Technology, Delft, The Netherlands

29.2: Erroneous Classifications in Electronic Noses (10:45) Due to Noise

K. L. Goodner U.S. Citrus and Subtropical Products Laboratory, Winter Haven, FL

J. G. Dreher, R. L. Rouseff University of Florida, Lake Alfred, FL

29.3: Dual-Use Signal Processing for a Multiple-Sensor System: Sonar and Optical Image Processing for Underwater Obstacle Avoidance

> T. M. Massengill, D. M. Wilson University of Washington, Seattle, WA

29.4: A New Nulling Method in the V-BLAST Under (11:15) Uncertain Channel Information

> K. Lee, J. Chun KAIST, Taejon, Korea

29.5: An Optical-Fiber Water Sensor Utilizing Signal- (11:30) Processing Techniques and Artificial Neural-Network Pattern Recognition

D. King, W. B. Lyons, C. Flanagan, E. Lewis University of Limerick, Castletroy, Limerick, Ireland

29.6: The Outer-Product as a Method for the Fusion (11:45) of Data from Different Electronic Noses

C. Di Natale, R. Paolesse University of Rome, Rome, Italy

G. Olafsdottir Icelandic Fisheries Laboratories, Reykjavik, Iceland

A. Macagnano IME-CNR, Lecce, Italy, and PSM-CNR, Rome, Italy

A. D'Amico University of Rome, Rome, Italy; IME-CNR, Lecce, Italy; and PSM-CNR, Rome, Italy

LUNCH

(12:00-1:30)

APPLICATIONS: AEROSPACE

Thur	sday, June 13 / 10:30 am – 12:00 pm / Ballro	om C
Chair	: Upendra Singh, NASA-Langley Research Center	, USA
30.1:	Combination of Low-Power Radars and Non- Rotating Sector Antennas for Surveillance of Ground Moving Traffic in Airports	(10:30)
	KH. Bethke, B. Röde, A. Schroth German Aerospace Center (DLR), Wessling, Germa	any
30.2:	Sensing and Perception Challenges in Planetary-Surface Robotics	(10:45)
	E. Tunstel, A. Howard NASA–Jet Propulsion Laboratory, Pasadena, CA	
30.3:	Thin-Film Strain-Gauge Sensors for Ion Thrust Measurement	(11:00)
	R. J. Stephen, K. Rajanna Indian Institute of Science, Bangalore, India	
	V. Dhar, K. G. K. Kumar, S. Nagabushanam ISRO Satellite Center, Bangalore, India	
30.4:	Embedded Micromachined Fiber-Optic Fabry– Perot Pressure Sensors for Aerodynamics Applications	(11 <mark>:15</mark>)
	M. J. Gander, W. N. MacPherson, J. S. Barton, R. L. Reuben, J. D. C. Jones Heriot-Watt University, Edinburgh, U.K.	
	R. Stevens Rutherford Appleton Laboratory, Didcot, U.K.	
	K. S. Chana, S. J. Anderson QinetiQ, Pyestock, Hampshire, U.K.	
	T. V. Jones Oxford University, Oxford, U.K.	
30.5:	Sensor Applications at Kennedy Space Center	(11:30)
	J. M. Perotti, A. Eckhoff NASA–Kennedy Space Center, Kennedy Space Cen	nter, FL
30.6:	Electromagnetic Sensors for Microsatellites	(11:45)
	V. Korepanov Lviv Center, Institute of Space Research, Lviv, Ukra	ine

LUNCH

(12:00-1:30)

Session 31

1

.

THERMAL SENSING I

Chair	: Kevin Kornegay, Cornell University, USA	
31.1:	Experimental Study of High-TCR Pt Thin Films for Thermal Sensors	(10:30
	K. Tsutsumi, A. Yamashita, H. Ohji Mitsubishi Electric Corp., Hyogo, Japan	
31.2:	Embedded Silver Halide Optical-Fiber Temperature Sensor	(10:45
	S. Sade, O. Eyal, A. Katzir Tel Aviv University, Tel Aviv, Israel	
31.3:	Ferroelectric Thin Films for Pyroelectric Sensors	(11:00)
	W. Liu, L. Sun, W. Zhu, O. K. Tan Nanyang Technological University, Singapore	
31.4:	A Reconstruction Technique for Stimulated- Brillouin-Scattering-Based Fiber-Optic Sensors for Simultaneous Measurement of Temperature and Strain	
	R. Bernini CNR-IREA, Naples, Italy	
	A. Minardo, L. Zeni Seconda Università di Napoli, Aversa, Italy	
31.5:	Multi-Sensors to Measure Pressure and Temperature Made from a New Polyacene Quinone Radical Polymer	(11:30)
	Q. Lei, Y. Fan, W. Zhang Harbin University of Science and Technology, Harb	oin, China
	F. Huang National Science Foundation Committee of China	
31.6:	The Chemistry and Physics of Doped BaTiO ₃ for PTCR Thermistors	(11:45)
	Z-G. Zhou, Z-L. Tang, Z-T. Zhang Tsinghua University, Beijing, China	
LUNC	(12	:00-1:30)

BIOSENSOR DEVELOPMENT IN MEDICAL APPLICATIONS I

Thur	rsday, June 13 / 1:30–3:00 pm / Ballroom	II		Chair
Chair	r: Sheila Grant, University of Missouri-Columb	ia, USA	,	33.1
32.1:	Invited Paper: Fiber-Optic Sensing of Tissue to Assess Low-Blood-Flow States	pH (1:30)		
	B. R. Soller, P. O. Idwasi, S. O. Heard University of Massachusetts Medical School, Worcester, MA			
32.2:	Invited Paper: Implantable Glucose Sensor: Progress and Problems	(2:00)		
	F. Moussy University of Connecticut Health Center, Farmington, CT			33.2:
32.3:	Immobilization of RET Biomolecules for an HIV Sensor	(2:30)		
	S. A. Grant University of Missouri, Columbia, MO			
	J. Xu Michigan Technological University, Houghton, M	I.		33.3:
32.4:	Acoustic Plate Mode Tissue Sensor	(2:45)		
	F. G. Tseng, K. C. Leou, Y. Y. Lai National Tsing Hua University, Taiwan, R.O.C.			33.4:
	L. C. Pan, Y. C. Liang, L. D. Chen Taipei Medical University, Taiwan, R.O.C.			
BREA	ĸ	(3:00–3:30)		33.5:
			×	
				33.6:

CHEMICAL SENSING II

Thursday, June 13 / 1:30-3:00 pm / Ballroom III

r:	Vasyl' V. II'chenko, Kiev Taras Shevchenko, University, L	Jkraine
:	Electrically Controlled Metal Oxide Gas Sensor Designed with PROSA-CHEM	(1:30)
	M. Scheinert, T. Doll Ilmenau Technical University, Ilmenau, Germany	
	J. Wöllenstein, H. Böttner Fraunhofer Institute of Physical Measurement Technic Freiburg, Germany	ques,
	H. P. Frechrichs, H. Verhoeven, M. Lehmann Micronas GmbH, Freiburg, Germany	
:	SnO ₂ Sensors with Variable Operating Temperature for CO Detection: Selectivity and Sensitivity Enhancement	(1:45)
	A. Burresi, A. Fort, S. Rocchi, B. Serrano, N. Ulivieri, V. Vignoli University of Siena, Siena, Italy	
	G. Sberveglieri, E. Zampiceni University of Brescia, Brescia, Italy	
:	Higher-Order Sensing Using QCM Sensor Array and Preconcentrator with Variable Temperature	(2:00)
	T. Nakamoto, K. Sukegawa, E. Sumitomo Tokyo Institute of Technology, Tokyo, Japan	
:	A Miniature pH Sensor Based on Pre-oxidized Petroleum Pitch-Based Carbon-Fiber Microelectro	(2:15) de
	Y-F. Tu, J-W. Di, P. Xu Suzhou University, Suzhou, People's Republic of Chir.	a
:	New Surface-Acoustic-Wave Gas Sensor of the Mass-Sensitive Type Sensitive to the Thermal	(2:30)

Properties of Gases R. G. Kryshtal, A. V. Medved Institute of Radio Engineering and Electronics, Russian Academy of Sciences, Moscow, Russia

33.6: Non-Cooled p-InAsSbP/n-InAs Photodiodes for (2:45) Detection of Pollutant Gases

V. I. Khivrych, N. M. Panchenko, A. V. Sukach, V. V. Tetyorkin Scientific Center Institute for Nuclear Research National Academy of Sciences of Ukraine, Kiev, Ukraine

N. V. Zotova, S. A. Karandashev, M. A. Matveev, N. M. Remennyi, B. A. Stus, G. N. Talalakin Institute of Semiconductor Physics, National Academy of Sciences of Ukraine, Kiev, Ukraine

BREAK

(3:00 - 3:30)

SMART SENSORS AND INTERFACE ELECTRONICS I

Thursday, June 13 / 1:30-3:00 pm / Ballroom A

Co-Chairs:

Gerard Meijer, Delft University of Technology, The Netherlands Kofi Makinwa, Delft University of Technology, The Netherlands

34.1: Invited Paper: CMOS Smart Temperature (1:30) Sensors: How to Improve Accuracy

A. Bakker Philips Semiconductors, Delft, The Netherlands

34.2: Invited Paper: Single-Chip CMOS Capacitive Gas (2:00) Sensor for Detection of Volatile Organic Compounds

> C. Hagleitner, A. Kummer, A. Hierlemann, H. Baltes Physical Electronics Laboratory, Zurich, Switzerland

34.3: Magnetoresistive Sensors and a New Hardware-Based Interpolation Method for Length and Angle Measurements

K. Leitis, W. Bonath University of Applied Sciences, Giessen, Germany

34.4: Switched-Capacitor Front End for Capacitance (2:45) Measurements with Extended Linear Range

V. P. lordanov, G. C. M. Meijer Delft University of Technology, Delft, The Netherlands

S. N. Nihtianov ASML, Veldhoven, The Netherlands

BREAK

(3:00 - 3:30)

MATERIALS AND FABRICATION I

Thursday, June 13 / 1:30-3:00 pm / Ballroom D

- Chair: Lina Sarro, Delft University of Technology, The Netherlands
- 35.1: Measurement of the Viscoelastic Constants of (1:30) a Sol-Gel Material by an Acoustic Method

M. Gindre, S. Serfaty, B. Senouci, L. Martinez, P. Griesmar Université de Cergy-Pontoise, Cergy, France

35.2: Fabrication and Characterization of Flexible (1:45) Silicon Substrates with Electroplated Gold Leads

T. Lisby, J. Branebjerg DELTA Danish Electronics, Hørsholm, Denmark

O. Hansen Technical University of Denmark

35.3: Novel Piezoelectric Materials for Advanced (2:00) Sensor Applications

P. W. Rehrig, E. Alberta, W. S. Hackenberger TRS Ceramics, Inc., State College, PA

T. R. Shrout The Pennsylvania State University, University Park, PA

35.4: Examination of Thin Porous Monolayer and (2:15) Multilayer Structures Containing an Underlayer of Porous Silicon

I. A. Leonov, O. P. Pchelyakov, K. P. Mogilnikov Institute of Semiconductor Physics, Novosibirsk, Russia

35.5: Micromechanical Structures Fabricated by an Electrochemical Process (2:30)

M. O. S. Dantas, E. Galeazzo, H. E. M. Peres, F. J. Ramirez-Fernandez São Paulo University, São Paulo, Brazil

35.6: Oxidized Porous-Silicon Thick Layers as (2:45) Substrates for RF/Microwave IC Applications

Y. Long East China Normal University, Shanghai, China, and Chang De Normal University, Chang De, China

Z. Zhu, Z. Lai, Y. Shi, P. Xin East China Normal University, Shanghai, China

BREAK

(3:00-3:30)

POSITION SENSORS I

Thur	sday, June 13 / 1:30–3:00 pm / Ballroom C		Thur	sday, Ju
Chair	: William Tang, DARPA, USA		Chair	: Fuqian
36.1:	Optical Sensors for the Velocity and Slip Measurement of Automobile Belt Drives	(1:30)	37.1:	Design a NTC The
	C. Berger Karlsruhe University, Karlsruhe, Germany			R. K. Kai Goa Uni
36.2:	Novel Semi-Transparent Optical Position Sensors for High-Precision Alignment Monitoring Applications	(1:45)	37.2:	Non-Idea Substrat
	V. Danielyan, S. Horvat, H. Kroha Max Planck Institute of Physics, Munich, Germany	v		M. A. P. I Delft Uni
36.3:	A Comparison of Layered Metal-Semiconducto Optical Position Sensitive Detectors	or (2:00)	37.3:	Influence Conduct
	J. Henry, J. Livingstone The University of Western Australia, Crawley, Wes	Nora		Z. Mokta Universit
	Australia			M. P. Bru Space R
36.4:	An Incremental Capacitive Sensor for Harsh Environments	(2:15)	27.4.	The Neth
	B. Brandsttter, G. Brasseur, S. Cermak, H. Zangl Graz University of Technology, Graz, Austria		57.4.	Sensor /
	P. L. Fulmek Vienna University of Technology, Vienna, Austria			C. Falcor Universit
36.5:	Application of MEMS for Improved Emitter-	(2:30)		J. H. Huij Delft Uni
	Location Accuracy	()	37.5:	Fiber-op
	N. E. Wu, M. L. Fowler State University of New York at Binghamton, Binghamton, NY			C. P. A. F Centro d
36.6:	On-Wafer Stiffness and Displacement Measurements of Freestanding MEMS Structures	(2:45)		del IPN, W. Fonse ESIME II
	R. Maggini, F. Gueissaz, D. Piguet ASULAB S.A., Marin, Switzerland		37.6:	Simultar Measure
BREA	к (3:00-3:30)		Grating

Session 37

THERMAL SENSING II

Thur	sday, June 13 / 1:30–3:00 pm / Ballroom F	
Chair	: Fuqian Yang, University of Kentucky, USA	
37.1:	Design and Development of High-Performance NTC Thermistors	(1:30)
	R. K. Kamat, G. M. Naik, V. M. S. Vernekar Goa University, Goa, India	
37.2:	Non-Idealities of Temperature Sensors Using Substrate PNP Transistors	(1:45)
	M. A. P. Pertijs, G. C. M. Meijer, J. H. Huijsing Delft University of Technology, Delft, The Netherlands	
37.3:	Influence of Surface Roughness on Heat Conductance in Silicon Cryogenic Sensors	(2:00)
	Z. Moktadir, R. J. Wiegerink, M. Elwenspoek University of Twente, Enschede, The Netherlands	
	M. P. Bruijn, M. Ridder, W. A. Mels Space Research Organization Netherlands, Utrecht, The Netherlands	
37.4:	A Model of Bipolar Transistors for Thermal- Sensor Applications	(2:15)
	C. Falconi, C. Di Natale, A. D'Amico University of Rome, Rome, Italy	
	J. H. Huijsing Delft University of Technology, Delft, The Netherlands	
37.5:	Fiber-optic Temperature Sensor for Use in Experimental Microwave Hyperthermia	(2:30)
	C. P. A. Pennisi, L. Leija Centro de Investigacion y de Estudios Avanzados del IPN, Mexico	
	W. Fonseca ESIME IPN, Mexico	
37.6:	Simultaneous Refractive Index and Temperature Measurement Using a Cascaded Long-Period Grating Device	(2:45)
	B. A. L. Gwandu, X. W. Shu, T. D. P. Allsop, W. Zhang, L. Zhang, D. J. Webb, I. Bennion Aston University, Birmingham, U.K.	

BREAK

(3:00-3:30)

BIOSENSOR DEVELOPMENT IN MEDICAL APPLICATIONS I

Thursday, June 13 / 3:30–5:00 pm / Ballroom II

Chair: Sheila Grant, University of Missouri-Columbia, USA

38.1: Invited Paper: A Kinetic Study of Analyte-Receptor Binding and Dissociation for DNA Biosensor Applications (3:30)

A. Ramakrishnan, A. Sadana University of Mississippi, University, MS

38.2: Invited Paper: Ion Concentrations in Live Cells (4:00) from Highly Selective Ion Correlation Fluorescent Nano-Sensors

> M. Brasuel, E. Park, R. Kopelman University of Michigan at Ann Arbor, Ann Arbor, MI

38.3: Invited Paper: Nanoengineering of Fluorescence- (4:30) Based Biochemical Sensors Using Molecular Self-Assembly: Thin Films and Micro/Nanoshells

> P. S. Grant, S. R. Nayak, T. Duchesne, K. Guice, Q. Brown, Y. Lvov, M. J. McShane Louisiana Tech University, Ruston, LA

CHEMICAL SENSING III

Thursday, June 13 / 3:30-4:45 pm / Ballroom III

Chair: Hiroaki Suzuki, University of Tsukuba, Japan

39.1: Transient-Response Chemical-Discrimination (3:30) Module

> S. Hoyt, S. McKennoch, D. M. Wilson University of Washington, Seattle, WA

39.2: Adaptive Temperature Modulation for CO/CH₄ (3:45) Concentration Assessment

A. Perera, T. Sundic, T. Pardo, S. Marco University of Barcelona, Barcelona, Spain

39.3: Identification of Organic Solvents by a Virtual (4:00) Multisensor System with Hierarchical Classification

> A. Schütze, A. Gramm, T. Rühl Saarland University, Saarbruecken, Germany

39.4: Electrochemical Detection of Chloride, Bromide, (4:15) and lodide by Monoatomic Films of Silver on Gold Electrodes

P. E. Laibinis, R. Michalitsch, P. Castaño, C. Bristow MIT, Cambridge, MA

39.5: Sol-Gel-Based Oxygen Sensor & Luminescence- (4:30) Lifetime-Based Instrumentation

J. C. Campo, M. A. Pérez, N. Barragán, C. Blanco, J. C. Viera University of Oviedo, Gijon, Spain

SMART SENSORS AND INTERFACE ELECTRONICS II

Thursday, June 13 / 3:30-5:00 pm / Ballroom A

Co-Chairs:

Gerard Meijer, Delft University of Technology, The Netherlands Kofi Makinwa, Delft University of Technology, The Netherlands

40.1: Invited Paper: Smart Silicon Sensors: Examples (3:30) of Hall-Effect Sensors and Capacitive Fingerprint Sensors

P. de Jong, G. C. M. Meijer Delft University of Technology, Delft, The Netherlands

40.2: Invited Paper: CMOS Microsystem for ac Current (4:00) Measurement with Galvanic Isolation

> V. Frick, L. Hebrard, P. Poure, F. Anstotz, F. Braun Laboratoire d'Électronique et de Physique des Systèmes Instrumentaux (LEPSI), Strasbourg, France

40.3: On-Chip Programmabilities and Temperature (4:30) Compensation

H. K. Trieu, N. Kordas, W. Mokwa Fraunhofer Institute of Microelectronic Circuits and Systems, Duisburg, Germany

40.4: High-Performance Photo Detector for Modulated (4:45) Lighting

Y. Oike, M. Ikeda, K. Asada The University of Tokyo, Tokyo, Japan

MAGNETIC SENSING I

Thur	sday, June 13 / 3:30–5:00 pm / Ballroom D	
Chair	: Z. Y. Zhou, Tsinghua University, China	
41.1:	A Novel Planar Mesh-Type Micro-Magnetic Sensor for the Quality Inspection of Electro-Plated Material	(3:30)
	S. C. Mukhopadhyay Massey University, Palmerston North, New Zealand	
41.2:	Neural-Network-Aided Estimation of Near- Surface Material Properties Using Planar Mesh-Type Micromagnetic Sensor	(3:45)
	S. C. Mukhopadhyay Massey University, Palmerston North, New Zealand	
41.3:	Giant Magneto-Impedance in Multilayers of Magnetic Amorphous Ribbons	(4:00)
	F. Amalou, M. A. M. Gijs Swiss Federal Institute of Technology, Lausanne, Switzerland	
41.4:	A Micro High-Temperature-Superconductor Magnet Flywheel System for Energy Storage, Power Generation, and Attitude Control	(4:15)
	E. Lee University of Texas at San Antonio, San Antonio, TX	
41.5:	Thermomagnetic Residual Offset in Integrated Hall Plates	(4:30)
	P. Ruther, U. Schiller, O. Paul IMTEK-Materials, Institute for Microsystem Technolog University of Freiburg, Freiburg, Germany	y.
	W. Buesser, R. Janke Micronas AG, Freiburg, Germany	

41.6: Magnetic Angular Encoder Using Automatic (4:45) Offset-Compensation Technique

M. Kayal, E. Chevallaz, F. Burger, R. Popovic Swiss Federal Institute of Technology, Lausanne, Switzerland

POSITION SENSORS II

Thursday, June 13 / 3:30-5:00 pm / Ballroom C

Chair: Star R. Huang, National Tsinghua University, Taiwan

42.1: A Class of MEMS Gyroscopes with Increased (3:30) Parametric Space

> C. Acar, A. Shkel University of California at Irvine, Irvine, CA

42.2: Wafer-Bonded High-Dynamic-Range Single-Crystal-Silicon Tunneling Accelerometer (3:45)

D. T. Chang, R. L. Kubena, F. P. Stratton, D. J. Vickers-Kirby, R. J. Joyce, J. Kim HRL Laboratories, LLC, Malibu, CA

42.3: Resolver Position-Sensing System with (4:00) Integrated Fault Detection for Automotive Applications

B. Hare, A. Murray, A. Hirao Analog Devices KK, Tokyo, Japan

42.4: Design and Realization of an Optical Bi-Axial (4:15) Miniature Inclination Sensor

J. Clijnen, W. Meeusen, D. Reynaerts, H. Van Brussel, R. Simons, K. Plessers K. U. Leuven, Heverlee, Belgium

42.5: Fiber-Bragg-Grating Sensors for Position (4:30) Monitoring in High-Energy Physics

> M. Bertani, S. Bianco, F. L. Fabbri, M. Giardoni, A. La Monaca, E. Pace, M. Pallotta Laboratori Nazionali di Frascati dell'INFN (LNF-INFN), Frascati, Italy

M. A. Caponero, L. Morici ENEA Frascati, Frascati, Italy, and LNF-INFN, Frascati, Italy

F. Felli, A. Paolozzi, A. Scicutelli Università degli Studi Roma, Rome, Italy, and LNF-INFN, Frascati, Italy

(4:45)

42.6: A Contactless Capacitive Angular Encoder

M. Gasulla, X. Li, G. C. M. Meijer Delft University of Technology, Delft, The Netherlands

Session 43

SENSOR SYSTEMS AND NETWORKS I Thursday, June 13 / 3:30-5:00 pm / Ballroom F Chair: Pedro Silva Girão, Lab Medidas Electricas, Portugal 43.1: Optimal Estimation Methodology for Flexible-(3:30)Structure Vibration Measurement J. Lin Ching Yun Institute of Technology, Taiwan, R.O.C. 43.2: Development Trends in Sensor Technology: (3:45)A New BCG Matrix Analysis as a Potential Tool of Technology Selection for a Sensor Suite J. P. Singh Instruments Research & Development Establishment, Dehra Dun, India 43.3: Next-Generation Technologies to Enable Sensor (4:00) Networks D. R. Martinez, M. Gruber MIT Lincoln Laboratory, Lexington, MA 43.4: Stabilizing Controller Design for Distributed (4:15)Sensor Networks with Time-Varying Delays V. R. Herath, K. Premaratne, M. Dogruel, P. H. Bauer University of Miami, Coral Gables, FL 43.5: An Architecture Supporting Monitoring and (4:30)Configuration in Real-Time Smart Transducer Networks P. Peti, R. Obermaisser, W. Elmenreich, T. Losert Vienna University of Technology, Vienna, Austria 43.6: Task-Oriented Self-Organization of Ad-Hoc (4:45)Sensor System J. Zhang, K. Premaratne, M. Dogruel University of Miami, Coral Gables, FL P. H. Bauer University of Notre Dame, Notre Dame, IN

POSTER SESSION II

Thursday, June 13 / 5:30-7:00 pm / Florida Hall East

MODELING/EVALUATION

P2.1: Membrane Modeling of Pull-In Instability in MEMS Sensors and Actuators

> F. Yang University of Kentucky, Lexington, KY

P2.2: Testing and Simulation of Novel MEMS Relays by Applying Digital Image Correlation Technology

> C-S. Wang, C-Y. Xiong, W-B. Zhang, J. Fang, Z-H. Li Peking University, Beijing, People's Republic of China

P2.3: A System-Level Model in VHDL-AMS for a Micromechanic Vibration Sensor Array

> M. Schlegel, G. Herrmann, D. Müller Chemnitz University of Technology, Chemnitz, Germany

P2.4: Modeling and Identification of a PZT-Driven Cantilever Actuator

> S-F. Ling, B. lu Nanyang Technological University, Singapore

P2.5: The Role of Structural Factors in In₂O₃ Gas Response

G. Koratcenkov, V. Brinzari, A. Cerneavschi, M. Ivanov Technical University of Moldova, Chisinau, Republic of Moldova

A. Cornet, J. Morante, A. Cabot, J. Arbiol Universität de Barcelona, Barcelona, Spain

V. Golovanov Odessa National University, Odessa, Ukraine

P2.6: Electrical Sensing Properties of Polypyrrol

M. Campos UNIP-Universidade Paulista, Ribeirão Preto, Brazil

P2.7: Super-Low-Temperature Sintering of Semiconducting-BaTiO₃-Based PTCR Ceramics

> Z-G. Zhou, X-F. Tang, Z-L. Tang Tsinghua University, Beijing, People's Republic of China

P2.8: A Ray-Tracing Approach for Simulating Recognition Abilities of Active Infrared Sensor Arrays

B. Iske, U. Rückert University of Paderborn, Paderborn, Germany P2.9: Numerical Modeling of Sensing and Actuating Electromechanical Transducers

> R. Lerch Universität Erlangen-Nürnberg Lehrstuhl für Sensorik, Erlangen, Germany

P2:10: Study on Dynamic Characteristic of the Silicon Micromachined Gyroscope with a Fence Structure

> X. Bin, L. Che, S. Fu, Y. Wang Shanghai University of Microsystem and Information Technology, Chinese Academy of Sciences, Shanghai, People's Republic of China

P2.11: Precise Calculation of Capacitances of Complex-Shaped Capacitive-Sensor Elements by the Method of Direct Field-Strength Determination

> G. M. Gorbova, M. M. Gorbov, G. C. M. Meijer Delft University of Technology, Delft, The Netherlands

P2.12: Investigation of SPR Technology Using Texas Instruments' Spreeta™ Sensor

> D. R. Sommers, D. D. Stubbs, W. D. Hunt Georgia Institute of Technology, Atlanta, GA

P2.13: Impedance Spectroscopic Study of MEMS Microphone

S. B. Lee, P. V. Loeppert Knowles Electronics, LLC, Itasca, IL

P2.14: Compensation of Packaging Asymmetry in a 2-D Wind Sensor

> S. P. Matova, K. A. A. Makinwa, J. H. Huijsing Delft University of Technology, Delft, The Netherlands

P2.15: Understanding the Long-Term and Analyte Exposure Effects on Tin Oxide Thick-Film Sensors

J. W. Allen, B. T. Marquis Sensor Research & Development Corp., Orono, ME

P2.16: Impact of Micro-Resonator Geometric Shape on Quality Factor Using Finite Elements with Dynamic Thermoelastic Coupling

J. Gorman MIT, Cambridge, MA, and Charles Stark Draper Laboratory, Cambridge, MA

A. Duwel Charles Stark Draper Laboratory, Cambridge, MA

P2.17: CAD Modeling and Fabrication of Planar Thin-Film Airflow Sensors

R. J. Adamec, P. Tanner, D. V. Thiel Griffith University, Nathan, Queensland, Australia

P2.18: Direct Calculation of Sensor Performance in a FEA Model

R. Krondorfer, T. C. Lommasson SensoNor asa.., Horten, Norway

P2.19: Characterization and Modeling of Ge-Film Thermometers for Low-Temperature Measurements

V. K. Dugaev National Academy of Sciences of Ukraine, Chernovtsy, Ukraine, and ISEL, Lisbon, Portugal

G. G. Ihas, C. McKenney University of Florida, Gainesville, FL

V. F. Mitin National Academy of Sciences of Ukraine, Chernovtsy, Ukraine, and MicroSensor Ltd., Kiev, Ukraine

M. Vieira ISEL, Lisbon, Portugal

P2.20: Smart Adaptable Strain Gage Conditioner

S. Poussier, H. Rabah, S. Weber Laboratoire d'Instrumentation Electonique de Nancy, Vandoeuvre les Nancy, France

P2.21: Mechanical and Thermal Sensors, Sensor Materials, and Fabrication Methods (Micro and Nanosensors)

F. W. Beil, R. H. Blick, A. Wixforth Ludwig-Maximilians-Universität, Müchen, Germany

D. Schuh, M. Bichler Universität Müchen, Garching, Germany

P2.22: A New Analytical Model for Detectivity Prediction of Resistance Bolometers

F. Kohl, A. Jachimowicz, F. Keplinger, R. Chabicovsky Vienna University of Technology, Wien, Austria

P2.23: Displacements and Rotations of Practical Vibrational Modes of Piezoelectric Bimorph Cantilever Beams

A. Ballato, Y. Kim U.S. Army CECOM, Fort Monmouth, NJ

P2.24: Determination of the Sensitivity Behavior of an Acoustic and Thermal Flow Sensor by Electronic Characterization

J. W. van Honschoten, T. S. J. Lammerink, G. J. M. Krijnen, M. C. Elwenspoek University of Twente, Enschede, The Netherlands

V. B. Svetovoy Institute of Microelectronics, Yaroslavl, Russia

P2.25: Withdrawn

P2.26: Withdrawn

P2.27: A Study in the Application of Multilayer Perceptrons to the Analysis of Sensor Systems Data

> M. Pardo, G. Sberveglieri INFM and University of Brescia, Brescia, Italy

ELECTROMAGNETIC PROPERTIES

P2.28: New Antenna Sensor for Temperature Control by Microwave Radiometry

V. Thomy, L. Dubois, C. Vanoverschelde, J. P. Sozanski, J. Pribetich Université de Lille, Villeneuve d'Ascq, France

P2.29: Application Fields of a Miniaturized Ion Mobility Spectrometer

T. Horvath, S. Sielemann, M. Teepe G.A.S. Gesellschaft für Analytische Sensorsysteme, Dortmund, Germany

J. I. Baumbach ISAS, Dortmund, Germany

P2.30: Eddy Field Mitigation in a Distributed Magnetic Local Positioning System

E. Prigge Stanford University, Stanford, CA

J. How MIT, Cambridge, MA

PRESSURE

P2.31: Pressure Transducers with Frequency Output on the Base of Strain-Sensitive Unijunction Transistors

G. G. Babichev, S. I. Kozlovskiy, V. A. Romanov, N. N. Sharan Institute of Semiconductor Physics, Ukraine Academy of Sciences, Kiev, Ukraine

ROBOTICS

P2.32: An Ultrasonic Obstacle Sensing System for Fire-Fighting Robot

F. Tong Southeast University, Nanjing, Jiangsu, People's Republic of China

L. Xu Xiamen University, Xiamen, People's Republic of China

D. Tong

Technical Center of Mingguang, Fire Fighting Equipment Factory of Anhui Province, Mingguang, People's Republic of China

P2.33: Local Discriminant Bases and Optimized Wavelet to Classify Ultrasonic Echoes: Application in Indoor Mobile Robotics

C. Barat CNRS, Sophia-Antipolis, France

P2.34: Application of an Extended Kalman Filter to Multiple Low-Cost Navigation Sensors in Wheeled Mobile Robots

I. A. R. Ashokaraj, P. Silson, A. Tsourdos Cranfield University, Wiltshire, U.K.

P2.35: Robot Soccer Using Analog VLSI Sensors

V. Becanovic, A. Bredenfeld, P. G. Ploeger Fraunhofer Institute for Autonomous Intelligent Systems, Sankt Augustin, Germany

P2.36: Controlling a Gas/Odor Plume-Tracking Robot Based on Transient Responses of Gas Sensors

H. Ishida, G. Nakayama, T. Nakamoto, T. Moriizumi Tokyo Institute of Technology, Tokyo, Japan

P2.37: A Novel Ultrasonic Sensing System for Autonomous Mobile Systems

D. Bank Research Institute for Applied Knowledge Processing, Ulm, Germany

P2.38: Sensor Application for Automation

R. Tanner, S. Kumar Western Michigan University, Kalamazoo, MI

P2.39: Design and Application of the Field-Bus-Based Intelligent Robot Plug-and-Play Sensing System

J. Zhang, Y. Ge, X. Wang, G. Song, J. Jiang University of Science and Technology, Hefei, People's Republic of China, and Chinese Academy of Sciences, Hefei, People's Republic of China

P2.40: Sensor Fusion for Ultrasonic and Laser Arrays in Mobile Robotics: A Comparative Study of Fuzzy, Dempster, and Bayesian Approaches

> R. H. Nezhad, B. Moshiri University of Tehran, Tehran, Iran

M. R. Asharif University of Ryukyus, Okinawa, Japan

AEROSPACE

P2.41: Satellite Attitude Acquisition Using Dual Star Sensors with a Bootstrap Filter

> S. Cho, J. Chun Korea Institute of Science & Technology, Taejon, Korea

P2.42: Latest Development in Advanced Sensors at Kennedy Space Center

> J. M. Perotti, A. Eckhoff, T. Erdogan Nasa-Kennedy Space Center, FL

P2.43: Air Target Detection Using Synthetic-Aperture Bistatic Radar with Non-Cooperative GPS-Based Transmitter: Case Study

B. Mojarrabi, J. Homer, K. Kubik The University of Queensland, Brisbane, Australia

P2.44: An Internet-Based Inverse-GPS System for Monitoring and Tracking Mobile Aquatic Sensors

B. J. Howell, J. Frolik Tennessee Technological University, Cookeville, TN

P2.45: Effectively Simultaneous Temperature and Strain Measurement Utilizing a Dual-Grating Sensor Formed by Type IA and IIA FBGs

X. Shu, Y. Liu, D. Zhao, B. Gwandu, F. Floreani, L. Zhang, I. Bennion Aston University, Birmingham, U.K.

THERMAL

P2.46: Micro-Electro-Mechanical Digital-to-Analog Converter Based on a Novel Bimorph Thermal Actuator

> Q. Liu, Q-A. Huang Southeast University, Nanjing, People's Republic of China

FRIDAY, JUNE 14

Session 44

Special Session

NEW TRENDS IN METAL OXIDE SEMICONDUCTING GAS SENSORS

Friday, June 14 / 8:30-10:00 am / Ballroom II

Chair: Giorgio Sberveglieri, University of Brescia, Italy

44.1: Invited Paper: Heteroepitaxy of Tungsten Oxide (8:30) Films on Sapphire and Silicon for Chemiresistive Sensor Applications

> R. J. Lad University of Maine, Orono, ME

44.2: Invited Paper: Mixed Nanostructured Oxides of Ti (9:00) and VI-B-Group Elements for Gas Sensing

> V. Guidi, E. Comini, G. Faglia, M. Ferroni Università di Ferrara, Ferrara, Italy

44.3: Invited Paper: New Materials and Technologies (9:30) for Micromachined Metal Oxide Gas Microsensor Arrays

J. Wöllenstein, H. Böttner Fraunhofer Institute of Physical Measurement Techniques, Freiburg, Germany

J. A. Plaza, C. Cané Centro Nacional de Microelectrónica, Barcelona, Spain

BREAK

(10:00-10:30)

66

SENSOR SYSTEM INTERFACES ON A CHIP

Friday, June 14 / 8:30–10:00 am / Ballroom III

Chair: Denise Wilson, University of Washington, USA

45.1: Just Add a Sensor: Integrating Analog and (8:30) Digital Signal Conditioning in a Programmable System-on-Chip

D. Seguine Cypress MicroSystems, Bothell, WA

45.2: Biologically Inspired Auditory-Sensing-System (9:00) Interfaces on a Chip

P. Hasler, P. D. Smith, R. Ellis, D. Graham, D. Anderson Georgia Institute of Technology, Atlanta, GA

45.3: Optical Chemical-Sensor-System Interfaces on (9:30) a Chip

K. S. Booksh, D. M. Wilson, L. A. Obando, M. Warren Arizona State University, Tempe, AZ

BREAK

Session 45

(10:00-10:30)

PHOTONIC SENSORS: OPTICAL PROPERTIES I

Friday, June 14 / 8:30-10:00 am / Ballroom A

Chair: Gerald Gerlach, Dresden University of Terchnology, Germany

46.1: Detectivity of NTC Thin-Film Sensor (8:30)M. Lee. M. Yoo Yeungnam University, Kyungsan, Korea 46.2: Biometric System Based on One Large-Area (8:45)a-SiC:H P-I-N Photodiode M. Vieira, M. Fernandes, A. Fantoni, P. Louro, R. Schwarz ISEL, Lisbon, Portugal 46.3: Visible Optical Sensing of Ammonia-Based (9:00)**Polyaniline Film** Y-S. Lee, N-J. Choi, B-T. Kim, J-S. Huh, D-D. Lee Kyungpook National University, Taegu, Korea 46.4: Optical-Fiber Sensor Using Tailored Porous (9:15)Sol-Gel Fiber Core S. Tao, C. B. Winstead, J. P. Singh, R. Jindal Mississippi State University, Starkville, MS 46.5: Optically Powered VCSEL-Based Miniaturized (9:30)E-Field Probe with High Sensitivity W. Mann, K. Petermann Technical University of Berlin, Berlin, Germany 46.6: Integrated Laser Doppler Velocimeter for Fluid-(9:45)**Velocity and Wall-Friction Measurements** P. Lemaître-Auger LCIS-INPG, Valence, France A. Cartellier LEGI-INPG-UJF, St. Martin d'Heres, France P. Benech, I. S. Duport IMEP-LEMO-INPG, Grenoble, France BREAK (10:00-10:30)

Session 47

Frida	y, June 14 / 8:30–10:00 am / Ballroom D	8
Chair	: Remis Gaska, Sensor Electronic Technology, Inc.,	USA
<mark>47.1</mark> :	Fabrication Technology for Closely Coupled Microcoils with Integrated Flux Guidance and Their Application to Proximity and Magnetoelastic Force Sensors	(8:30)
	V. Seidemann, S. Büttgenbach Technical University of Braunschweig, Braunschweig, Germany	
47.2:	Single-Crystal-Silicon MEMS Fabrication Technology Using Proton-Implantation Smart-Cut Technique	(8:45)
	J. Du, D. J. Young, W. H. Ko Case Western Reserve University, Cleveland, OH	
47.3:	GaPO4 Crystals for Sensor Applications	(9:00)
	P. M. Worsch, P. W. Krempl, F. Krispel, C. Reiter, H. Thanner, W. Wallnöfer AVL List GmbH, Graz, Austria	
47.4:	Investigation and Characterization of β-Ga ₂ O ₃ Nano-Wire for Gas-Sensing Applications	(9:15)
	M. Z. Atashbar Western Michigan University, Kalamazoo, MI	
	M-F. Yu Zyvex Corp., Richardson, TX	
	X. Chen Institute of Physics and Center for Condensed Matter Physics, Chinese Academy of Sciences, Beijing, China	3
47.5:	Fabrication of Poly-Germanium-Based Thermopiles on Plastic	(9:30)
	M. Moradi, A. Moafi, S. Mohajerzadeh University of Tehran, Tehran, Iran	
47.6:	Sensors for Harsh Environments by Direct- Write Thermal Spray	(9:45)
	S. Sampath, J. Longtin, R. J. Gambino, S. Tankiewicz State University of New York at Stony Brook, Stony Brook, NY	
	R. Greenlaw Integrated Coating Solutions, Inc., Huntington Beach,	CA
BREA	K (10:00–	10.201

Special Session

NANOMETRIC SENSING

Friday, June 14 / 8:30-10:00 am / Ballroom C

Co-Chairs: Takahito Ono, Tohoku University, Japan Masayoshi Esashi, Tohuku University, Japan

48.1: Invited Paper: Ultimate Sensing with an Ultrathin (8:30) Single-Crystal-Silicon Resonator

T. Ono Tohoku University, Sendai, Japan

48.2: Invited Paper: Micromachined Nano Devices: (9:00) From MEMS to Electron Devices

H. Hashiguchi Kagawa University, Japan, and Japan Science and Technology Corp., Tokyo, Japan

H. Fujita University of Tokyo, Tokyo, Japan and Japan Science and Technology Corp., Tokyo, Japan

48.3: Analog Fiber-Optic Position Sensor with (9:30) Nanometric Resolution

F. Lamarque, C. Prelle Université de Technologie de Compiègne, Compiègne, France

48.4: One-Micron-Precision Optically Aligned Method (9:45) for Hot-Embossing and Nano-Imprinting

P. Lindner, C. Schaefer EV Group, Schaerding, Austria

B. Wieder, R. Islam EV Group U.S., Inc., Phoenix, AZ

BREAK

(10:00-10:30)

Session 49

SENSOR SYSTEMS AND NETWORKS II

Friday, June 14 / 8:30-10:00 am / Ballroom F

Chair: Sukhan Lee, SAIT, Korea

49.1: Fault-Tolerance Techniques for Sensor Networks (8:30)

F. Koushanfar University of California at Berkeley, Berkeley, CA

M. Potkonjak University of California at Los Angeles, Los Angeles, CA

49.2: Signal Architecture for a Distributed Magnetic (8:45) Local-Positioning System

> E. Prigge Stanford University, Stanford, CA

J. How Massachusetts Institute of Technology, Cambridge, MA

49.3: Limitations of Emergent Wireless Sensor Networks: A Plea for Advancement in Core Technologies

> N. Correal, M. R. Perkins Motorola, Inc., Fort Lauderdale, FL

49.4: An Autonomous 16-mm³ Solar-Powered Node (9:15) for Distributed Wireless Sensor Networks

B. Warneke, M. Scott, B. Leibowitz, L. Zhou, C. Bellew, J. M. Kahn, B. E. Boser, K. S. J. Pister University of California at Berkeley, Berkeley, CA

49.5: Esbus: A Sensor Bus Based on the SPI Serial (9:30) Interface

H. S. Prasad State University of New York at Buffalo, Amherst, NY

D. Wobschall Esensors, Inc., Amherst, NY

49.6: Dynamic Link Labels for Energy-Efficient MAC (9:45) Headers in Wireless Sensor Networks

G. Kulkarni, C. Schurgers, M. Srivastava University of California at Los Angeles, Los Angeles, CA

BREAK

(10:00-10:30)

(9:00)

71

Special Session

CHEMICAL SENSOR INTERFACES AND LAB-ON-CHIP WITH INTEGRATED SENSOR ARRAYS I

Friday, June 14 / 10:30 am - 12:00 pm / Ballroom II

Chair: Gerald Urban, IMTEK, Germany

50.1: Invited Paper: Microarrays for Protein and (10:30)**Nucleic Acid Analysis**

> R. Ekins University College London, London, U.K.

50.2: Invited Paper: Microfluidic Devices for Trapping (11:00) Manipulation of Biological Nano-Particles

M. Dürr, J. Kentsch, M. Stelzle Natural & Medical Sciences Institute, Reutlingen, Germany

G. Gradl. T. Schnelle Evotec Analytical Systems GmbH, Hamburg, Germany

P. Geggier, M. Jäger FhG IBMT, Berlin, Germany

A. Haage, A. Normann Mediagnost GmbH, Reutlingen, Germany

R. Hagedorn, T. Müller Humboldt Universität zu Berlin, Berlin, Germany

G. Fuhr FhG IBMT, St. Ingbert, Germany

50.3: Frequency-Selective Sensor Arrays for (11:30)**Vibration Measurement**

> D. Scheibner, J. Mehner, B. Brämer, T. Gessner, W. Dötzel Chemnitz University of Technology, Chemnitz, Germany

50.4: Metabolomic Chips for Clinical Monitoring

I. Moser, G. Jobst, G. Urban University of Freiburg, Freiburg, Germany

LUNCH

(12:00-1:30)

(11:45)

Friday, June 14 / 10:30 am - 12:00 pm / Ballroom III

Chair: Denise Wilson, University of Washington, USA

(10:30)51.1: Invited Paper: New CMOS Gas Sensors and Devices

SYSTEMS

J. W. Gardner University of Warwick, Coventry, U.K.

F. Udrea Cambridge University, Coventry, U.K.

51.2: Invited Paper: Vapor Detection, Classification, (11:00)and Quantification Performance Using Arrays of Conducting Polymer-Composite Chemically Sensitive Resistors

> N. S. Lewis, S. Briglin, M. S. Freund, B. Sisk, E. Tillman California Institute of Technology, Pasadena, CA

(11:30)51.3: Invited Paper: ChemFET Arrays for Chemical-Sensing Microsystems

B. J. Polk Georgia Institute of Technology, Atlanta, GA

LUNCH

Session 51

(12:00-1:30)

PHOTONIC SENSORS: OPTICAL PROPERTIES II

Frida	ay, June 14 / 10:30 am – 12:00 pm / Ballroom	n A	Cha
Chai	r: Pietro Siciliano, IME-CNR Lab, Italy		Cha 53.1
52.1:	A Wavelength Sensor Using an Optical Directional Coupler	(10:30)	
	S. Somkuarnpanit, S. Jaturuntruengsri, S. Khoontha King Mungkut's Institute of Technology, Bangkok, Tu	aweetep hailand	53.2
52.2:	Novel Optical Distance Sensor Based on MSM Technology	(10:45)	
	P. Gulden, D. Becker, M. Vossiek Siemens AG, Munich, Germany		
52.3:	Ultra-Stabilization of Temperature in APD Sensors by Means of a High-Frequency Switching Regulator	(11:00)	53.3
	M. A. Pérez, J. C. Campo, F. J. Ferrero, J. C. Antón University of Oviedo, Gijon, Spain		
52.4:	Accurate and Real-Time Doppler Frequency Estimation with Multiplicative Noise for Velocity Measurements Using Optical- Feedback Interferometry	(11:15)	53.4
	G. Plantier, A. Sourice École Supérieure d'Électronique de l'Ouest (ESEO) Angers, France		53.5
	T. Bosch ENSEEIHT, France		
	N. Servagent École des Mines de Nantes, France		
52.5:	A Novel Silicon MIS Photodetector Using Molecular Semiconductor as Intermediate Oxide Layer	(11:30)	
	A. Malik, J. L. Sosa, S. Alcántara INAOE, Puebla, Mexico		
	Tunable Mid-Infrared Receiving Sensors Made of In _x Ga _{1-x} As/Al _y Ga _{1-y} As/Al _z Ga _{1-z} As Asymmetric Step Quantum-Well Structure	(11:45)	53.6
	W. G. Wu Peking University, Beijing, China		

LUNCH

(12:00-1:30)

Session 53

MATERIALS AND FABRICATION III Friday, June 14 / 10:30 am - 12:00 pm / Ballroom D : Taesong Kim, KIST, Korea Thermally Activated Aging of Polysilicon (10:30)M. Ehmann, P. Ruther, F. Schubert, O. Paul University of Freiburg, Freiburg, Germany New Substrates for MOEMS (10:45)M. Reiche Max-Planck-Institut für Mikrostrukturphysik, Halle, Germany E. Hiller, D. Stolze CIS Institut für Mikrosensorik GmbH, Erfurt, Germany **Enhancement of the Low-Temperature** (11:00)**Response of Thin-Film Gas Sensors by UV** Irradiation E. Comini, L. Ottini, G. Faglia, G. Sberveglieri Università di Brescia, Brescia, Italy Investigation of Different Passivation (11:15)Technologies for Thin-Film Sensors on **Ceramic Substrates** U. Schmid, G. Krötz EADS Deutschland GmbH, Munich, Germany **Optical and Electrical Gas-Sensing Properties** (11:30)of In_xO_vN_z Films M. Ando National Institute of Advanced Industrial Science & Technology (AIST), Osaka, Japan H. Steffes Technical University Berlin, Berlin, Germany R. Chabicovsky, G. Stangl Vienna University of Technology, Vienna, Austria M. Haruta Research Institute for Green Technology, AIST, Ibaraki, Japan Simulation and Design of a Silicon Drag-Force (11:45)Gas-Flow Sensor Based on the Piezoresistive Effect V. A. Kolchuzhin, A. V. Shaporin Novosibirsk State Technical University, Novosibirsk, Russia LUNCH (12:00 - 1:30)75

POSITION SENSORS III

Friday, June 14 / 10:30-12:00 am / Ballroom A

Chair: Star R. Huang, National Tsinghua University, Taiwan

54.1: A Novel Torsion Fiber Sensor Based on High-Birefringence Fiber Bragg Grating (10:30)

> Y-L. Lo, B-R. Chue National Cheng Kung University, Taiwan, R.O.C.

54.2: Array of PZT Pyroelectric Thick-Film Sensors (10:45) for Contactless Measurement of XY Position

V. Ferrari, A. Ghisla, D. Marioli, A. Taroni Università di Brescia, Brescia, Italy

54.3: Geometrical and Physical Models of a 3-D (11:00) Range Finder

> C. Barat, J. Triboulet, E. College, F. Chavand, E. C. N'Zi Université d'Evry Val d'Essonne, Evry, France

54.4: Low-Cost Magnetic Torque Sensor (11:15)

H. Ruser, U. Tröltzsch, M. Horn, H.-R. Tränkler University of Bundeswehr Munich, Neubiberg, Germany

54.5: A Gazing-Point-Distance Detection System (11:30) for Accommodation Assisting Glasses

> T. Fujita, S. Sato, M. Idesawa University of California at Berkeley, Berkeley, CA

54.6: A New Two-Axis Magnetic Position Sensor (11:45)

C. Schott, R. Racz, F. Betschart SENTRON AG, Zug, Switzerland

R. S. Popovic Swiss Federal Institute of Technology, Lausanne, Switzerland

LUNCH

(12:00-1:30)

Session 55

SENSOR SYSTEMS AND NETWORKS III

Friday, June 14 / 10:30 am - 12:00 pm / Ballroom F

Chair: Pedro Silva Girão, Lab Medidas Electricas, Portugal

55.1: Architecture, Feasibility Study, and a Prototype (10:30) of a Vestibular Implant Using 3-Axes MEMS Gyroscopes

> A. M. Shkel, J. Liu, F-G. Zeng University of California at Irvine, Irvine, CA

55.2: An Internet and Microcontroller-Based Remote (10:45) Operation Multi-Sensor System for Water-Quality Monitoring

> O. Postolache, P. S. Girão, J. M. D. Pereira, H. G. Ramos Laboratório de Medidas Eléctricas, Lisbon, Portugal

55.3: Remote Process Monitoring Using Optical-Fibre Sensors (11:00)

> B. Degamber, G. F. Fernando Cranfield University, Swindon, U.K.

55.4: An Integrated Framework for Internet-Based (11:15) Applications of Smart Sensors

> M. Sveda, R. Vrba Brno University of Technology, Brno, Czech Republic

55.5: A Low-Cost Internet-Enabled Smart Sensor (11:30)

P. Ferrari, A. Flammini, D. Marioli, A. Taroni Università di Brescia, Brescia, Italy

55.6: Enhanced Multiplexing Capacity of Low-Coherence Reflectometric Sensors Based on a Loop Topology (11:45)

L. Yuan Harbin Engineering University, Harbin, China

W. Jin, L. Zhou, Y. L. Hoo Hong Kong Polytechnic University, Hong Kong, China

LUNCH

(12:00 - 1:30)

SENSOR SYSTEMS AND NETWORKS III

Friday, June 14 / 1:30-3:00 pm / Ballroom II

Chair: Gerald Urban, IMTEK, Germany

56.1: Invited Paper: Can MicroTAS Be Alternatives (1:30) for Sensors?

J. C. T. Eijkel, O. P. Naji, P. Monaghan, A. Manz Imperial College, London, U.K.

56.2: Invited Paper: A Multi-Layer Plastic Packaging (2:00) Technology for Miniaturized Bio Analysis Systems Containing Integrated Electrical and Mechanical Functionality

> A. Han, O. Wang, S. K. Mohanty, M. Graff, A. B. Frazier Georgia Institute of Technology, Atlanta, GA

56.3: A Novel Fluidic Network System for Enzyme (2:30) Batch Immobilization and Blood Sensing

> F. G. Tseng, K. H. Lin, C. C. Chieng National Tsing Hua University, Taiwan, R.O.C.

56.4: Multifunctional Magnetofluidic Device: (2:45) Ampermeter, Protection Relay, and Actuator

C. D. Buioca, A. Stanci, V. Iusan University of Petrosani, Petrosani, Romania

M. Buioca High School Vulcan, Petrosani, Romania

BREAK

(3:00-3:30)

GAS SENSING I

Frida	ay, June 14 / 1:30-3:00 pm / Ballroom III	
Chair	: Ghenadi Korotcenkov, Technical University of Mo Moldavia	oldavia,
57.1:	Gas-Sensing Properties of Catalytically Modified WO3 with Copper and Vanadium for NH3 Detection	(1:30)
	I. Jiménez, A. Vilà, A. Cornet, J. R. Morante University of Barcelona, Barcelona, Spain	
57.2:	Resistance Noise Spectroscopy of SnO Thick-Film Gas Sensors	(1:45)
	J. M. Parks, B. T. Marquis, G. P. Harmer Sensor Research & Development Corp., Orono, ME	
57.3:	Metal Oxides for Gas Sensing with Field-Effect Devices	(2:00)
	I. Eisele, M. Burgmair Universität der Bundeswehr München, Neubiberg, Ge	ermany
57.4:	Gas Selective Barrier Organic Sensors	(2:15)
	V. Khivrych Institute for Nuclear Research, National Academy of Sciences, Kiev, Ukraine	
	Ya. Vartsimakha, I. Veklych Institute of Physics, National Academy of Sciences, Kiev, Ukraine	
57.5:	Low-Drift Air-Gap CMOS-FET Gas Sensor	(2:30)
	R. Paris, S. Pawel, R. Herzer, T. Doll Ilmenau Technical University, Ilmenau, Germany	
	P. Kornetzky IMMS GmbH, Ilmenau, Germany	
	G. Eranna, R. P. Gupta CEERI, Pilany, India	

57.6: Effects of Proton Implantation on Selectivity (2:45) Enhancement of Sputter-Deposited Indium Tin Oxide Gas Sensors

> A. Salehi K. N. T. University of Technology, Tehran, Iran

BREAK

(3:00-3:30)

PHOTONIC SENSORS: OPTICAL PROPERTIES III

Friday, June 14 / 1:30-3:00 pm / Ballroom A

Chair: R. Salathe, EPFL, Switzerland

58.1: A Multiplexed Point-Temperature Fiber Sensor (1:30) Array Using the OTDR Technique and TDM Mechanism

G. Hewa-Gamage University of New South Wales, Sydney, Australia

58.2: Geometry Measurements Using Self-Mixing (1:45) Interference in a Semiconductor Laser

T. Bosch ENSEEIHT, Toulouse, France

S. Donati University of Pavia, Pavia, Italy

N. Servagent École des Mines de Nantes, Nantes, France

58.3: Novel FTO/SRO/Silicon Optical Sensors: (2:00) Characterization and Applications

A. Malik, M. Aceves, S. Alcántara INAOE, Puebla, Mexico

58.4: Photosensors Based on Transient Processes (2:15) in MIS Structures with a Leak Insulator

A. Malik, A. Kosarev INAOE, Puebla, Mexico

58.5: Practical Diffraction-Limited Angle-Sensitive (2:30) Detectors

A. García-Valenzuela, G. E. Sandoval-Romero Universidad Nacional Autónoma de México, Universitaria, México

58.6: Development and Investigation of Narrow-Band (2:45) Luminescent Coatings for Ultraviolet Optical-Fiber Sensors

M. McSherry, C. Fitzpatrick, E. Lewis University of Limerick, Limerick, Ireland

BREAK

(3:00 - 3:30)

Session 59

MAGNETIC SENSING II

Frida	ay, June 14 / 1:30–3:00 pm / Ballroom D	
Chair	: Kofi Makinwa, Delft University of Technology, De The Netherlands	lft,
5 <mark>9.1</mark> :	Miniaturized Inductive Sensors for Industrial Applications	(1:30)
	M. Jagiella, S. Fericean Balluff GmbH, Neuhausen, Germany	
59.2:	Current Sensor in PCB Technology	(1:45)
	P. Ripka Czech Technical University, Czech Republic	
	M. Duffy, W. G. Hurley National University of Ireland, Galway, Ireland	
	S. O'Reilly National Microelectronic Research Center, Cork, Irel	and
59.3:	Horizontal Hall-Effect Sensor with High Maximum Absolute Sensitivity	(2:00)
	J-B. Kammerer, L. Hebrard, V. Frick, P. Poure, F. Brau Laboratoire d'Electronique et de Physique des Systè Instrumentaux, Strasbourg, France	
59.4:	Electro-Magneto-Mechanical Sensors Based on Parametric Oscillation Circuits	(2:15)
	E. Ejiogu, T. Kawabata, Y. Tanno Ritsumeikan University, Shiga, Japan	
59.5:	Epitaxial Iron Garnet Film as an Active Medium of the Fluxgate Transducer	(2:30)
	S. B. Ubizskii, Lviv Polytechnic National University, Lviv, Ukraine, and R&D Institute for Materials, Scientific Research Company, Lviv, Ukraine	
	P. M. Vetoshko Institute of Radioengineering and Electronics, Academy of Sciences of Russia, Moscow, Russia	
	M. V. Valeiko, P. I. Nikitin General Physics Institute, Academy of Sciences of Russia, Moscow, Russia	
59.6:	Radiation-Resistant Magnetic Sensor Material	(2:45)
	A. Ya. Karpenko, V. I. Khivrych, G. A. Vikhliy Institute for Nuclear Research, National Academy of Sciences, Kiev, Ukraine	
	I. Ya. Kulynyak Drogobych Pedagogical University, Ukraine	

LUNCH

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(3:00-3:30)

ELECTROMECHANICAL BEHAVIOR OF MEMS SENSORS AND ACTUATORS

Friday, June 14 / 1:30-3:50 pm / Ballroom C

Chair: Fuqian Yang, University of Kentucky, USA

60.1: Invited Paper: Optical Applications with SOI-Based MEM Technology (1:30)

N. Jia, J. Kubby, P. Gulvin, J. Diehl, L. Herko, J. Chen, P. Nystrom, K. Feinberg, J. Ma, K. German Xerox Corp., Webster, NY

B. Scharf, A. Zosel Microscan Systems, Inc., Renton, WA

D. Kharas, N. De Lanerolle, A. Seck, R. Mali, T. Pumo, C. Nichols Standard MEMS, Inc., Hauppauge, NY

M. Rosa, D. DeBruyker, E. Peters Xerox Palo Alto Research Center, Palo Alto, CA

J. Gilbert, T. Korsmeyer, A. Morris, T. Plowman, V. Rabinovich, B. Stoll Coventor Technologies, Cary, NC

60.2: Invited Paper: Analysis of Flow Rate through (2:00) Rectangular Orifices of MEMS Valves with Experimental Results

Y. Li, G. Wang, Y-H. Su, I. Kao SUNY at Stony Brook, Stony Brook, NY

60.3: Invited Paper: Electrostatic MEMS Actuator: (2:30) Fundamental Studies of the Actuator and Failure Mechanism

N. Jia, J. Kubby, J. Diehl, P. Nystrom, P. Gulvin, K. Feinberg, J. Kuang, J. Chen Xerox Corp., Webster, NY

BREAK

(3:00-3:30)

Session 61

PRESSURE SENSORS I

Friday, June 14 / 1:30-3:00 pm / Ballroom F

- Chair: Chiang Lu, University of Illinois at Urbana-Champaign, USA
- 61.1: Micro-Torque Measurement Based on the (1:30) Cable-Brake Principle

W. Brenner, A. Vujanic, G. Popovic Vienna University of Technology, Vienna, Austria

O. Del Medico INOCON Technologie, Voecklabruck, Austria

61.2: Self-Energized Wireless Pressure Sensor Using (1:45) Energy Extraction from Injection-Mold Pressure Differential

> C. Theurer, L. Zhang, R. Gao, D. Kazmer University of Massachusetts, Amherst, MA

61.3: Sapphire-Based Capacitive Pressure Sensor (2:00) for High-Temperature and Harsh-Environment Applications

> M. Soeda, T. Kataoka, Y. Ishikura, S. Kimura, T. Masuda, Y. Yoshikawa, M. Nagata Yamatake Corp., Kanagawa, Japan

61.4: A Study on the Development of a Thin-Film (2:15) Pressure Sensor

> Y. Mihara, T. Someya Musashi Institute of Technology, Tokyo, Japan

61.5: A Micromachined Self-Resonant-Frequency (2:30) Modulated Passive Pressure Transensor

> A. Baldi, W. Choi, B. Ziaie University of Minnesota, Minneapolis, MN

61.6: Pressure Sensor Based on Distributed (2:45) Temperature Sensing

J. J. Van Baar, R. J. Wiegerink, J. W. Berenschot, T. S. J. Lammerick, G. J. M. Krijnen, M. Elwenspoek University of Twente, Enschede, Netherlands

BREAK

(3:00-3:30)

APPLICATIONS: BIOMEDICAL

Friday, June 14 / 3:30-5:00 pm / Ballroom II

Chair: Shanhong Xia, Chinese Academy of Sciences, China

62.1: A Novel System for Measuring Optical (3:30) Properties in the Arterial Blood of Man

> A. Castaneda-Miranda Instituto de Fisica, U.N.A.M., Mexico

62.2: A Biomedical Smart Sensor for the Visually (3:45) Impaired

> L. Schwiebert, G. Auner, S. Gupta, P. Siy, R. Iezzi, G. Abrams Wayne State University, Detroit, MI

62.3: Microcomputer-Based Acceleration Sensor (4:00) Device for Sports Biomechanics Stroke Evaluation by Using Swimmer's Wrist Acceleration

Y. Ohgi Keio University, Kanagawa, Japan

62.4: Non-Invasive and Unrestrained Monitoring of the Human Respiratory System by Sensorized Environment

Y. Nishida, T. Hori Digital Human Laboratory, National Institute of Advanced Industrial Science and Technology, Tokyo, Japan

62.5: Miniature Fiber-Optic Pressure Sensor for (4:30) Medical Applications

E. Cibula, D. Donlagic University of Maribor, Maribor, Slovinia

62.6: Wireless Level-Sensing Restaurant Glassware (4:45)

P. Dietz, W. S. Yerazunis, D. Leigh Mitsubishi Electric Research Laboratories, Cambridge, MA

GAS SENSING II

Friday, June 14 / 3:30-5:00 pm / Ballroom III Chair: Jaco Visser, Ford Research Laboratory, USA 63.1: Low-Cost High-Performance Gas Analytical (3:30)**Gradient Microarrays for Intelligent Consumer Products** C. Arnold, W. Andlauer, D. Haeringer, R. Koerber, J. Goschnick Institut für Instrumentelle Analytik, Karlsruhe, Germany 63.2: Enhanced Catalytic Activity of Ultra-Thin CuO (3:45)Islands on SnO₂ Films for Fast-Response H₂S **Gas Sensors** A. Chowdhuri, V. Gupta, K. Sreenivas University of Delhi, Delhi, India 63.3: Study of Gas Sensor Based on Adsorption (4:00)Heat Measurement Using Y-Cut Quartz-Crystal Microbalance A. Saitoh, Y. Asari, T. Nomura Shibaura Institute of Technology, Tokyo, Japan 63.4: Contribution of the Gate Insulator to Work-(4:15)Function Measurements with a Gas-Sensor FET M. Burgmair, I. Eisele Universität der Bundeswehr München, Neubiberg, Germany 63.5: Characteristics and Gas-Sensing Properties (4:30)of Mechanochemically Processed Iron-Doped SnO₂ Nanoparticles L. Cukrov, P. G. McCormick The University of Western Australia, Crawley, Australia K. Galatsis RMIT University, Melbourne, Australia 63.6: H₂S-sensing Characteristics of SnO₂-Based (4:45)**Composite Film Gate MIS Diodes** X. He, J. Li, X. Gao, L. Wang Institute of Electronics, Chinese Academy of Science,

Beijing, People's Republic of China

MATERIALS AND FABRICATION IV

Friday, June 14 / 3:30-5:00 pm / Ballroom A

Chair: Yuelin Wang, Shanghai Institute of Metallurgy, China

64.1:	Surface-Effect Humidity Sensors Based on	(3:30)
	Alumina and Porous Silicon Materials, Electrical	
	Parameters, Sensitivity, and Internal Noises	

D. K. An, L. H. Mai, N. T. Ha, N. T. Kien, N. T. Binh Institute of Materials, National Center for Natural Science and Technology, Hanoi, Vietnam

64.2: Humidity-Sensing Properties of Organic-Inorganic (AMPS/SiO₂) Hybrid Materials (3:45)

W-H. Tao Chinese Cultural University, Taipei, Taiwan

L-Y. Sung ITRI/Energy and Resource Laboratories, Hsinchu, Taiwan, R.O.C.

C-C. Hung Chung-Tuan Christian University, Chungli, Taiwan, R.O.C.

C-L. Hsu Yuanpei Institute of Science and Technology, Hsinchu, Taiwan, R.O.C.

64.3: Nanostructured TiO(2) Thin Films Prepared by Supersonic Beams and Their Application in a Sensor Array for the Discrimination of VOC

T. Toccoli, A. Boschetti, L. Guerini, S. lannotta Sezione Istituto Fotonica e Nanotecnolgie, Trento, Italy

S. Capone, A. Taurino, P. Siciliano IME-CNR Sezione IMM, Lecce, Italy

64.4: A Microfabricaton Strategy for Cylindrical-Ion-Trap Mass-Spectrometer Arrays (4:15)

H. Peddanenikalva, S. Bhansali, R. T. Short, D. P. Fries University of South Florida, Tampa, FL

64.5: Plasma-Sprayed Thick-Film Anisotropic-Magnetoresistive (AMR) Sensors (4:30)

> R. Gambino, M. M. Raja, S. Sampath The State University of New York, Stony Brook, NY

R. Greenlaw Integrated Coating Solutions, Inc., Huntington Beach, CA

64.6: Microfabricated Liquid-Core Waveguides for (4:45) Microanalysis Systems

> R. Manor, A. Datta, A. Dhar, M. Holtz, J. Berg, S. Gangopadhyay, P. Dasgupta, H. Temkin, V. Veeraraaghavan, R. Vijayaraghavan, T. Dallas Texas Tech University, Lubbock, TX

Session 65

MAGNETIC SENSING III

Frida	y, June 14 / 3:30–5:00 pm / Ballroom D	
Chair	: Z. Y. Zhou, Tsinghua University, China	
65.1:	Comparison of Surface H-Field Measurements Using Hall Sensors and a Novel Multiple Sense Coil Approach	(3:30)
	O. Hovorka, G. Lloyd, M. L. Wang University of Illinois at Chicago, Chicago, IL	
65.2:	Application of a GMR Line Sensor for Non-Destructive Testing	(3:45)
	Y. Kataoka, H. Wakiwaka Shinshu University, Nagano, Japan	
	O. Shinoura TDK Corp., Chiba, Japan	
65.3:	Magnetic Sensors with Poly-Si TFTs	(4:00)
	E. Carvou, F. Le Bihan, R. Rogel, O. Bonnaud Université Rennes, Rennes, France	
65.4:	Experimental Evaluation of Differential Thermal Errors in Magnetoelastic Stress Sensors	(4:15)
	G. Lloyd, V. Singh, M. L. Wang University of Illinois at Chicago, Chicago, IL	
65.5:	Developments in a Family of Integrated CMOS Magnetic Sensor/Actuators for Two-Phase Brushless dc Motor Control	(4:30)
	P. Riendeau, M. White Melexis, Inc., Concord, NH	
	V. Hiligsmann Melexis, Inc., Tessenderlo, Belgium	
65.6:	Development of Large-Area Iron Garnet Indicator Layers for Magneto-Optic Visualization	(4:45)
	I. M. Syvorotka, P. S. Kostyuk R&D Institute for Materials, Lviv, Ukraine	
	S. B. Ubizskii R&D Institute for Materials, Lviv, Ukraine, and Lviv Polytechnic National University, Lviv, Ukraine	

ELECTROMECHANICAL SYSTEMS

Friday, June 14 / 3:30-5:00 pm / Ballroom C

Chair: Pritpal Singh, University of Villanova, USA

66.1: Invited Paper: Pressure Belt: An Integrated (3:30) Multisensor System

> M. H. Tanielian, N. P. Kim Boeing Phantom Works, Seattle, WA

66.2: Invited Paper: Microsystems Based on Surface (4:00) Micromachined Mechanisms

A. Oliver, F. J. Peter Sandia National Laboratories, Albuquerque, NM

66.3: Invited Paper: Development of a Fuzzy-Logic-Managed Microscopic Battery (4:30)

R. LaFollette Bipolar Technologies, Provo, UT

P. Singh Villanova University, Philadelphia, PA

J. Broadhead U.S. Nanocorp.

PRESSURE SENSORS II

Frida	ay, June 14 / 3:30–5:00 pm / Ballroom F	
Chair	: Thomas Papakostas, Tekscan Inc., USA	
67.1:	A Highly Sensitive Fabry-Perot Shear-Stress Sensor Employing Flexible Membrane and Double SU-8 Structures	(3:30)
	F-G. Tseng, C. J. Lin National Tsing Hua University, Taiwan, R.O.C.	
67.2:	Development of Six-Degree-of-Freedom Micro- Force Sensor for Applications in Geophysics	(3:45)
	D. V. Dao, J. C. Wells, S. Sugiyama Ritsumeikan University, Shiga, Japan	
	T. Toriyama New Energy and Industrial Technology Development Organization, Japan	
67.3:	A New Pressure Sensor Measured by Heat Transfer	(4:00)
	H. Ohji, N. Yutani, M. Taruya, A. Koshimizu, S. Kodama, K. Tsutsumi Mitsubishi Electric Corp., Hyogo, Japan	
67.4:	Development of an Optical Force Sensor Usable in fMRI Environments	(4:15)
	S. Sasaki, M. Tada, T. Ogasawara Nara Institute of Science and Technology, Nara, Japa	n
67.5:	Combined Effect of the Membrane Flatness Defect and Real Dimension Gauges on the Sensitivity of a Silicon Piezoresistive Pressure Sensor	(4:30)
	Z. Dibi Université de Batna, Batna, Algeria	
	A. Boukabache, P. Pons LAAS-CNRS, Toulouse, France	
67.6:	SiN Beam Resonant Pressure Sensors with a Novel Structure	(4:45)
	D. Chen, D. Cui, L. Wang Institute of Electronics, Chinese Academy of Science. Beijing, People's Republic of China	s,

IEEE SENSORS 2002 EXHIBITORS

Florida Hall West

Tuesday: 7:00 am – 9:00 pm Wednesday: 9:00 am – 5:00 pm Thursday: 9:00 am – 5:00 pm Friday: 9:00 am – 12:00 pm

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